

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

SLOS218F – DECEMBER 1998 – REVISED JANUARY 2005

- Supply Current . . . 23 μ A/Channel
- Gain-Bandwidth Product . . . 220 kHz
- Output Drive Capability . . . ± 10 mA
- Input Offset Voltage . . . 20 μ V (typ)
- V_{DD} Range . . . 2.7 V to 6 V
- Power Supply Rejection Ratio . . . 106 dB
- Ultralow-Power Shutdown Mode
 I_{DD} . . . 16 nA/ch
- Rail-To-Rail Input/Output (RRIO)
- Ultrasmall Packaging
 - 5 or 6 Pin SOT-23 (TLV2450/1)
 - 8 or 10 Pin MSOP (TLV2452/3)

Operational Amplifier



description

The TLV245x is a family of rail-to-rail input/output operational amplifiers that sets a new performance point for supply current and ac performance. These devices consume a mere 23 μ A/channel while offering 220 kHz of gain-bandwidth product, much higher than competitive devices with similar supply current levels. Along with increased ac performance, the amplifier provides high output drive capability, solving a major shortcoming of older micropower rail-to-rail input/output operational amplifiers. The TLV245x can swing to within 250 mV of each supply rail while driving a 2.5-mA load. Both the inputs and outputs swing rail-to-rail for increased dynamic range in low-voltage applications. This performance makes the TLV245x family ideal for portable medical equipment, patient monitoring systems, and data acquisition circuits.

FAMILY PACKAGE TABLE

DEVICE	NUMBER OF CHANNELS	PACKAGE TYPES					SHUTDOWN	UNIVERSAL EVM BOARD
		PDIP	SOIC	SOT-23	TSSOP	MSOP		
TLV2450	1	8	8	6	—	—	Yes	Refer to the EVM Selection Guide (Lit# SLOU060)
TLV2451	1	8	8	5	—	—	—	
TLV2452	2	8	8	—	—	8	—	
TLV2453	2	14	14	—	—	10	Yes	
TLV2454	4	14	14	—	14	—	—	
TLV2455	4	16	16	—	16	—	Yes	

A SELECTION OF SINGLE-SUPPLY OPERATIONAL AMPLIFIER PRODUCTS[†]

DEVICE	V_{DD} (V)	BW (MHz)	SLEW RATE (V/ μ s)	I_{DD} (per channel) (μ A)	RAIL-TO-RAIL
TLV245X	2.7 – 6.0	0.22	0.11	23	I/O
TLV247X	2.7 – 6.0	2.8	1.5	600	I/O
TLV246X	2.7 – 6.0	6.4	1.6	550	I/O
TLV277X	2.5 – 6.0	5.1	10.5	1000	O

[†] All specifications measured at 5 V.



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TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

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description (continued)

Three members of the family (TLV2450/3/5) offer a shutdown terminal for conserving battery life in portable applications. During shutdown, the outputs are placed in a high-impedance state and the amplifier consumes only 16 nA/channel. The family is fully specified at 3 V and 5 V across an expanded industrial temperature range (-40°C to 125°C). The singles and duals are available in the SOT23 and MSOP packages, while the quads are available in TSSOP. The TLV2450 offers an amplifier with shutdown functionality all in a 6-pin SOT23 package, making it perfect for high density circuits.

TLV2450 and TLV2451 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES			
	SMALL OUTLINE (D) [†]	SOT-23		PLASTIC DIP (P)
		(DBV)	SYMBOL	
0°C to 70°C	TLV2450CD TLV2451CD	TLV2450CDBV TLV2451CDBV	VAQC VARC	TLV2450CP TLV2451CP
-40°C to 125°C	TLV2450ID TLV2451ID	TLV2450IDBV TLV2451IDBV	VAQI VARI	TLV2450IP TLV2451IP
	TLV2450AID TLV2451AID	— —	— —	TLV2450AIP TLV2451AIP

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2450CDR).

TLV2452 and TLV2453 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES						
	SMALL OUTLINE (D) [†]	MSOP				PLASTIC DIP (N)	PLASTIC DIP (P)
		(DGK) [†]	SYMBOL [‡]	(DGS) [†]	SYMBOL [‡]		
0°C to 70°C	TLV2452CD TLV2453CD	TLV2452CDGK —	xxTIABI —	— TLV2453CDGS	— xxTIABK	— TLV2453CN	TLV2452CP —
-40°C to 125°C	TLV2452ID TLV2453ID	TLV2452IDGK —	xxTIABJ —	— TLV2453IDGS	— xxTIABL	— TLV2453IN	TLV2452IP —
	TLV2452AID TLV2453AID	— —	— —	— —	— —	— TLV2453AIN	TLV2452AIP —

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2452CDR).

[‡] xx represents the device date code.

TLV2454 and TLV2455 AVAILABLE OPTIONS

T _A	PACKAGED DEVICES		
	SMALL OUTLINE (D) [†]	PLASTIC DIP (N)	TSSOP (PW) [†]
0°C to 70°C	TLV2454CD TLV2455CD	TLV2454CN TLV2455CN	TLV2454CPW TLV2455CPW
-40°C to 125°C	TLV2454ID TLV2455ID	TLV2454IN TLV2455IN	TLV2454IPW TLV2455IPW
	TLV2454AID TLV2455AID	TLV2454AIN TLV2455AIN	TLV2454AIPW TLV2455AIPW

[†] This package is available taped and reeled. To order this packaging option, add an R suffix to the part number (e.g., TLV2454CDR).

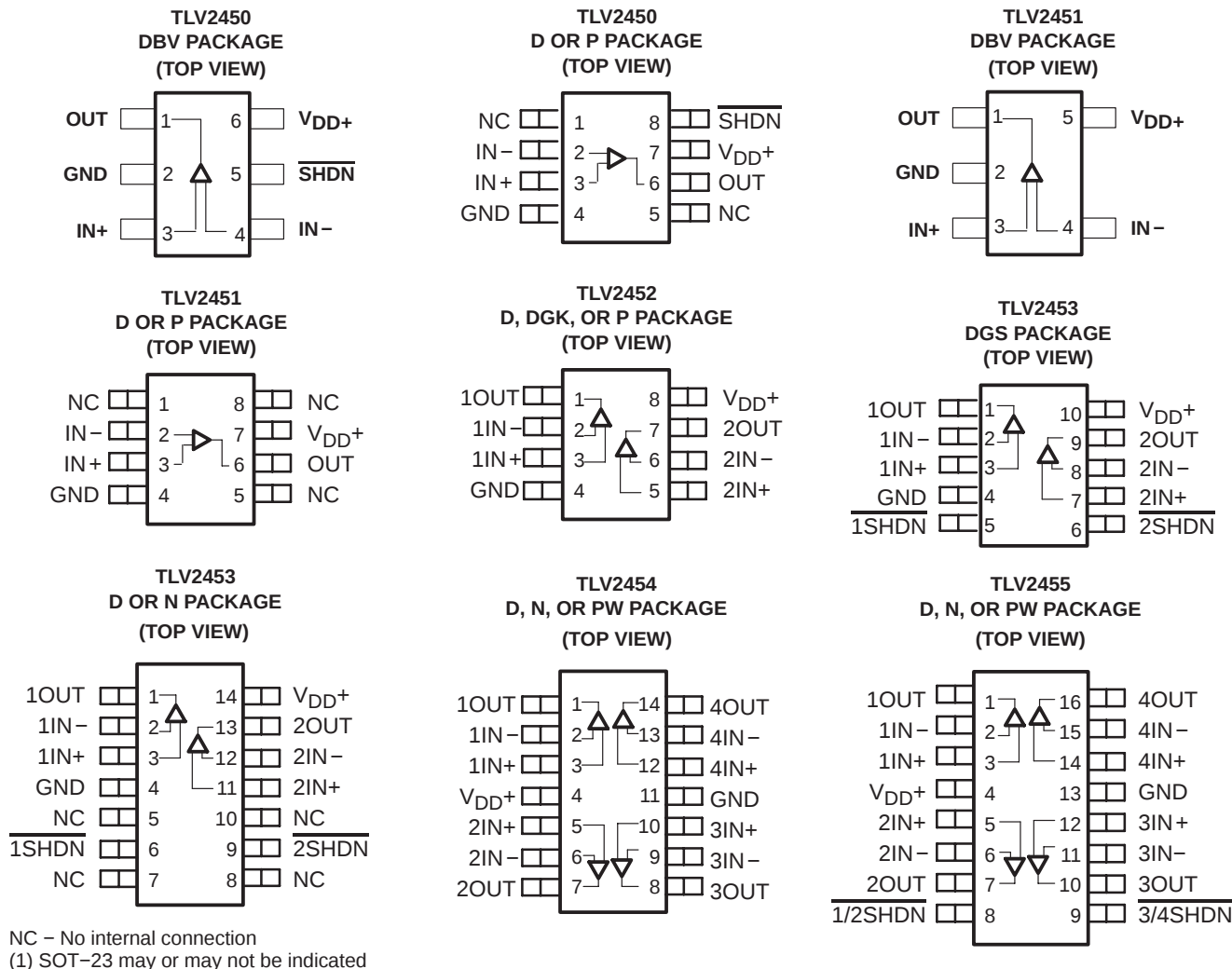
NOTE: For the most current package and ordering information, see the Package Option Addendum located at the end of this data sheet, or refer to our web site at www.ti.com.



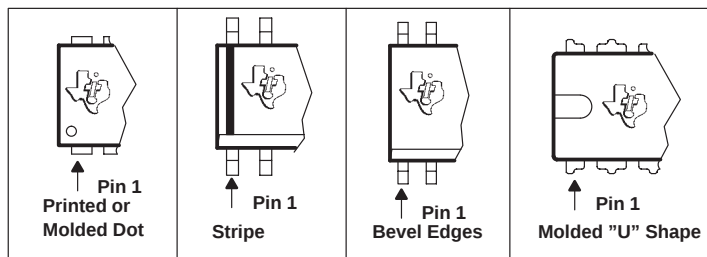
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TLV245x PACKAGE PINOUTS⁽¹⁾



TYPICAL PIN 1 INDICATORS



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{DD} (see Note 1)	7 V
Differential input voltage, V_{ID}	$\pm V_{DD}$
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T_A : C suffix	0°C to 70°C
I suffix	–40°C to 125°C
Maximum junction temperature, T_J	150°C
Storage temperature range, T_{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE: All voltage values, except differential voltages, are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	θ_{JC} (°C/W)	θ_{JA} (°C/W)	$T_A \leq 25^\circ\text{C}$ POWER RATING
D (8)	38.3	176	710 mW
D (14)	26.9	122.3	1022 mW
D (16)	25.7	114.7	1090 mW
DBV (5)	55	324.1	385 mW
DBV (6)	55	294.3	425 mW
DGK (8)	54.2	259.9	481 mW
DGS (10)	54.1	257.7	485 mW
N (14, 16)	32	78	1600 mW
P (8)	41	104	1200 mW
PW (14)	29.3	173.6	720 mW
PW (16)	28.7	161.4	774 mW

recommended operating conditions

		MIN	MAX	UNIT
Supply voltage, V_{DD}	Single supply	2.7	6	V
	Split supply	± 1.35	± 3	
Common-mode input voltage range, V_{ICR}		0	V_{DD}	V
Operating free-air temperature, T_A	C-suffix	0	70	°C
	I-suffix	–40	125	
Shutdown on/off voltage level [‡]	V_{IH}		2	V
	V_{IL}	$V_{DD} = 5V$	0.8	
		$V_{DD} = 3V$	0.5	V

[‡] Relative to voltage on the GND terminal of the device.



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electrical characteristics at specified free-air temperature, $V_{DD} = 3$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	MIN	TYP	MAX	UNIT	
V _{IO}	Input offset voltage	TLV245x	V _{DD} = ±1.5 V V _{IC} = 0, V _O = 0, R _S = 50 Ω	25°C	300		1500	μV	
				Full range	2000				
	TLV245xA			25°C	300		1000		
				Full range	1300				
α _{VIO}	Temperature coefficient of input offset voltage					0.3			μV/°C
I _{IO}	Input offset current				25°C	0.3		4.5	nA
					Full range	5.5			
I _{IB}	Input bias current				25°C	0.9		5	nA
				Full range	7				
V _{OH}	High-level output voltage	V _{IC} = 1.5 V,	I _{OH} = −500 μA	25°C	2.85	2.95		V	
				Full range	2.83				
V _{OL}	Low-level output voltage	V _{IC} = 1.5 V,	I _{OL} = 500 μA	25°C	0.09		0.16	V	
				Full range	0.2				
I _{OS}	Short-circuit output current	Sourcing		25°C	4	12		mA	
				Full range	3				
		Sinking		25°C	2	7			
				Full range	1				
I _O	Output current	V _O = 0.5 V from rail		25°C	±4		mA		
A _{VD}	Large-signal differential voltage amplification	V _{O(PP)} = 1 V,	R _L = 10 kΩ	25°C	96	110		dB	
				Full range	91				
r _{i(d)}	Differential input resistance			25°C	10 ⁹		Ω		
C _{IC}	Common-mode input capacitance	f = 10 kHz		25°C	4.5		pF		
z ₀	Closed-loop output impedance	f = 10 kHz,	A _V = 10	25°C	80		Ω		
CMRR	Common-mode rejection ratio	V _{IC} = 0 to 3 V, R _S = 50 Ω		25°C	70	80		dB	
			TLV245xC	Full range	66		dB		
k _{SVR}	Supply voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{DD} = 2.7 V to 6 V, No load	V _{IC} = V _{DD} /2,	25°C	76	89		dB	
				Full range	74				
		V _{DD} = 3 V to 5 V, No load	V _{IC} = V _{DD} /2,	25°C	88	106			
				Full range	84				
I _{DD}	Supply current (per channel)	V _O = 1.5 V, No load		25°C	23		35	μA	
			TLV245xC	Full range	40				
			TLV245xI	Full range	45				
I _{DD(SHDN)}	Supply current in shutdown mode (TLV2450, TLV2453, TLV2455) (per channel)	SHDN = −V _{DD}		25°C	12		65	nA	
			TLV245xC	Full range	70				
			TLV245xI	Full range	80				

† Full range is 0°C to 70°C for C suffix and –40°C to 125°C for I suffix.



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operating characteristics at specified free-air temperature, $V_{DD} = 3\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V _{O(PP)} = 0.8 V, R _L = 10 kΩ		25°C	0.05	0.11		V/μs
				Full range	0.02			
V _n	Equivalent input noise voltage	f = 100 Hz		25°C		49		nV/√Hz
		f = 1 kHz		25°C		51		
I _n	Equivalent input noise current	f = 1 kHz		25°C		3.5		pA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 1.5 V, R _L = 10 kΩ, f = 1 kHz	A _V = 1	25°C		0.04%		
			A _V = 10			0.3%		
			A _V = 100			1.5%		
t _(on)	Amplifier turnon time	A _V = 5, R _L = OPEN, Measured at 50% point		25°C		59		μs
t _(off)	Amplifier turnoff time			25°C		836		ns
Gain-bandwidth product		f = 10 kHz, R _L = 10 kΩ		25°C		200		kHz
t _s	Settling time	V _{(STEP)PP} = 2 V, A _V = -1, C _L = 10 pF, R _L = 10 kΩ	0.1%	25°C		26		μs
			0.01%			31		
		V _{(STEP)PP} = 2 V, A _V = -1, C _L = 56 pF, R _L = 10 kΩ	0.1%			26		
			0.01%			31		
φ _m	Phase margin	R _L = 10 kΩ, C _L = 1000 pF		25°C		56°		
Gain margin		R _L = 10 kΩ, C _L = 1000 pF		25°C		7		dB

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix.

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electrical characteristics at specified free-air temperature, $V_{DD} = 5$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	MIN	TYP	MAX	UNIT	
V _{IO}	Input offset voltage	TLV245x	V _{DD} = ±2.5 V V _{IC} = 0, V _O = 0, R _S = 50 Ω	25°C	300		1500	μV	
				Full range	2000				
				TLV245xA	25°C	300			1000
					Full range	1300			
α _{VIO}	Temperature coefficient of input offset voltage					0.3			μV/°C
I _{IO}	Input offset current				25°C	0.3		4.5	nA
					Full range	5.5			
I _{IB}	Input bias current				25°C	0.5		5	nA
					Full range	7			
V _{OH}	High-level output voltage		V _{IC} = 2.5 V, I _{OH} = -500 μA	25°C	4.87	4.97		V	
				Full range	4.85				
V _{OL}	Low-level output voltage		V _{IC} = 2.5 V, I _{OL} = 500 μA	25°C	0.07		0.15	V	
				Full range	0.16				
I _{OS}	Short-circuit output current		Sourcing	25°C	20	32		mA	
				Full range	18				
			Sinking	25°C	12	18			
				Full range	10				
I _O	Output current		V _O = 0.5 V from rail	25°C	±10		mA		
A _{VD}	Large-signal differential voltage amplification		V _{O(PP)} = 3 V, R _L = 10 kΩ	25°C	96	103		dB	
				Full range	91				
r _{i(d)}	Differential input resistance			25°C	10 ⁹		Ω		
C _{IC}	Common-mode input capacitance		f = 10 kHz	25°C	4.5		pF		
z _O	Closed-loop output impedance		f = 10 kHz, A _V = 10	25°C	45		Ω		
CMRR	Common-mode rejection ratio		V _{IC} = 0 to 5 V, R _S = 50 Ω	TLV245xC	25°C	70	80	dB	
					Full range	68			
k _{SVR}	Supply voltage rejection ratio (ΔV _{DD} /ΔV _{IO})		V _{DD} = 2.7 V to 6 V, No load	V _{IC} = V _{DD} /2,	25°C	76	89	dB	
					Full range	74			
			V _{DD} = 3 V to 5 V, No load	V _{IC} = V _{DD} /2,	25°C	88	106		
					Full range	84			
I _{DD}	Supply current (per channel)		V _O = 2.5 V, No load		25°C	23		42	μA
				TLV245xC	Full range	44			
				TLV245xI	Full range	46			
I _{DD(SHDN)}	Supply current in shutdown mode (TLV2450, TLV2453, TLV2455) (per channel)		SHDN = -V _{DD}		25°C	16		70	nA
				TLV245xC	Full range	70			
				TLV245xI	Full range	80			

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix.



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operating characteristics at specified free-air temperature, $V_{DD} = 5$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		T _A [†]	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V _{O(PP)} = 2 V, R _L = 10 kΩ		25°C	0.05	0.11		V/μs
				Full range	0.02			
V _n	Equivalent input noise voltage	f = 100 Hz		25°C		49		nV/√Hz
		f = 1 kHz		25°C		52		
I _n	Equivalent input noise current	f = 1 kHz		25°C		3.5		pA/√Hz
THD + N	Total harmonic distortion plus noise	V _{O(PP)} = 3 V, R _L = 10 kΩ, f = 1 kHz	A _V = 1	25°C		0.02%		
			A _V = 10			0.18%		
			A _V = 100			0.9%		
t _(on)	Amplifier turnon time	A _V = 5, R _L = OPEN,		25°C		59		μs
t _(off)	Amplifier turnoff time	Measured at 50% point		25°C		836		ns
Gain-bandwidth product		f = 10 kHz,	R _L = 10 kΩ	25°C		220		kHz
t _s	Settling time	V(STEP) _{PP} = 2 V, A _V = -1, C _L = 10 pF, R _L = 10 kΩ	0.1%	25°C		24		μs
			0.01%			30		
		V(STEP) _{PP} = 2 V, A _V = -1, C _L = 56 pF, R _L = 10 kΩ	0.1%			25		
			0.01%			30		
φ _m	Phase margin	R _L = 10 kΩ,	C _L = 1000 pF	25°C		56°		
Gain margin		R _L = 10 kΩ,	C _L = 1000 pF	25°C		7		dB

† Full range is 0°C to 70°C for C suffix and -40°C to 125°C for I suffix.

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TYPICAL CHARACTERISTICS

Table of Graphs

			FIGURE
V_{IO}	Input offset voltage	vs Common-mode input voltage	1, 2
I_{IO}	Input offset current	vs Common-mode input voltage vs Free-air temperature	3, 4 7, 8
I_{IB}	Input bias current	vs Common-mode input voltage vs Free-air temperature	5, 6 7, 8
A_{VD}	Differential voltage amplification	vs Frequency	9, 10
	Phase	vs Frequency	9, 10
V_{OL}	Low-level output voltage	vs Low-level output current	11, 13
V_{OH}	High-level output voltage	vs High-level output current	12, 14
Z_o	Output impedance	vs Frequency	15, 16
CMRR	Common-mode rejection ratio	vs Frequency	17
PSRR	Power supply rejection ratio	vs Frequency	18
I_{DD}	Supply current	vs Supply voltage	19
I_{DD}	Supply current	vs Free-air temperature	20
V_n	Equivalent input noise voltage	vs Frequency	21
THD + N	Total harmonic distortion plus noise	vs Frequency	22, 23
ϕ_m	Phase margin	vs Load capacitance	24
	Gain-bandwidth product	vs Supply voltage	25
SR	Slew rate	vs Supply voltage vs Free-air temperature	26 27
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	28
	Crosstalk	vs Frequency	29, 30
	Small-signal follower pulse response	vs Time	31, 33
	Large-signal follower pulse response	vs Time	32, 34
	Shutdown on supply current	vs Time	35
	Shutdown off supply current	vs Time	36
	Shutdown supply current	vs Free-air temperature	37
	Shutdown supply current	vs Time	38 – 41
	Shutdown pulse	vs Time	38 – 41
	Shutdown off pulse response	vs Time	42, 43
	Shutdown on pulse response	vs Time	44, 45
	Shutdown reverse isolation	vs Frequency	46
	Shutdown forward isolation	vs Frequency	47



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TYPICAL CHARACTERISTICS

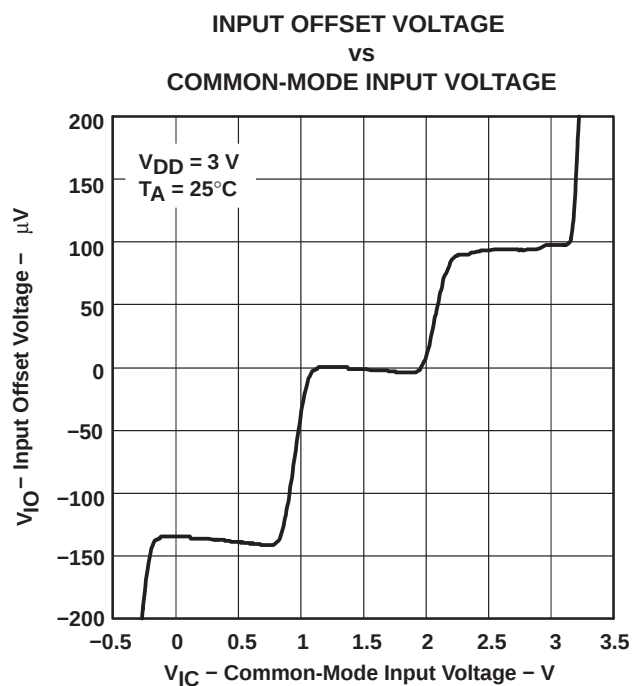


Figure 1



Figure 2



Figure 3



Figure 4

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
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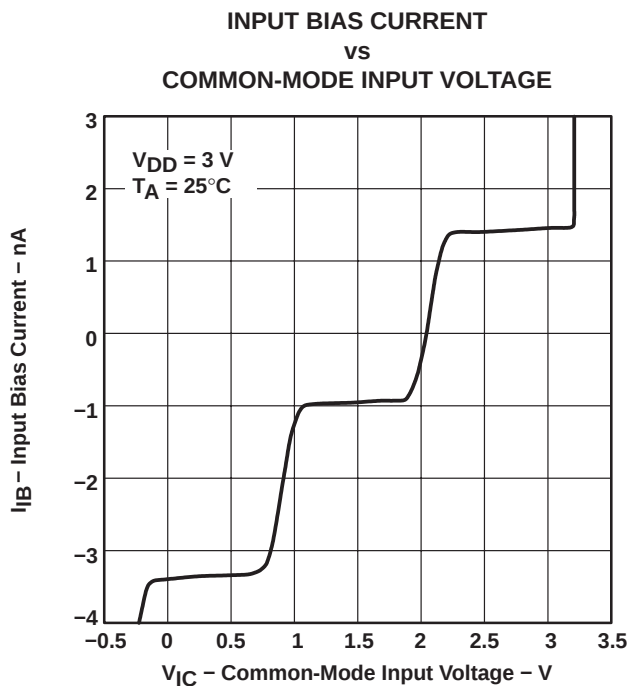


Figure 5

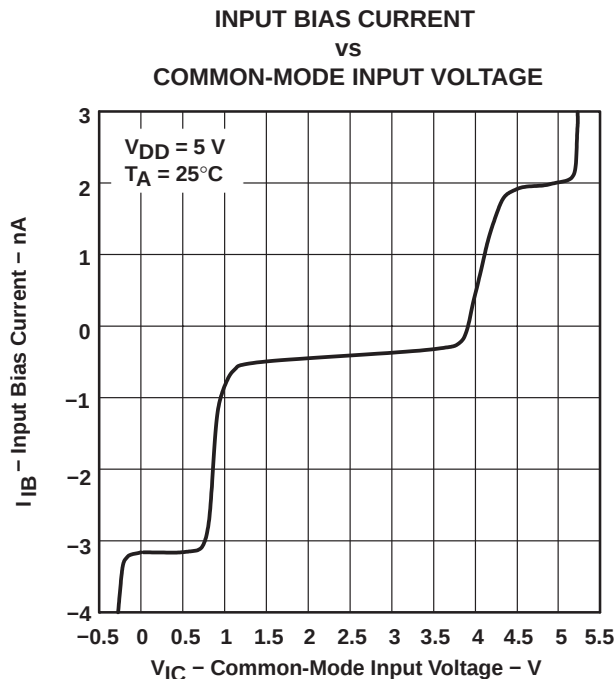


Figure 6

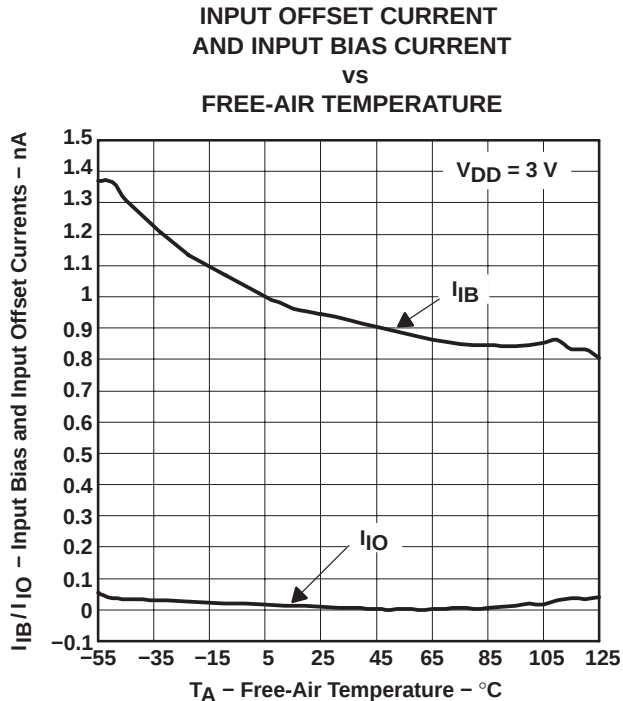


Figure 7

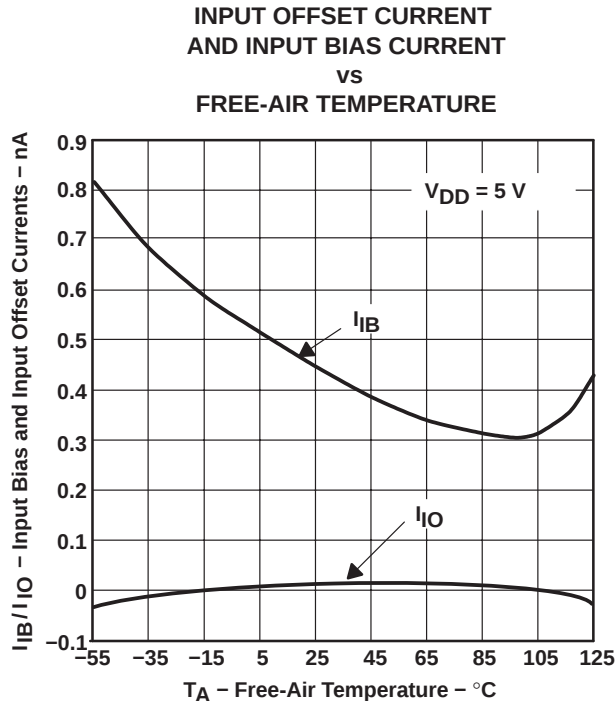


Figure 8

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TYPICAL CHARACTERISTICS

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE VS FREQUENCY



Figure 9

DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE VS FREQUENCY



Figure 10

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
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TYPICAL CHARACTERISTICS



Figure 11



Figure 12



Figure 13



Figure 14

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 15



Figure 16



Figure 17

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 18



Figure 19



Figure 20



Figure 21

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

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TYPICAL CHARACTERISTICS

TOTAL HARMONIC DISTORTION PLUS NOISE
VS
FREQUENCY



Figure 22

TOTAL HARMONIC DISTORTION PLUS NOISE
VS
FREQUENCY

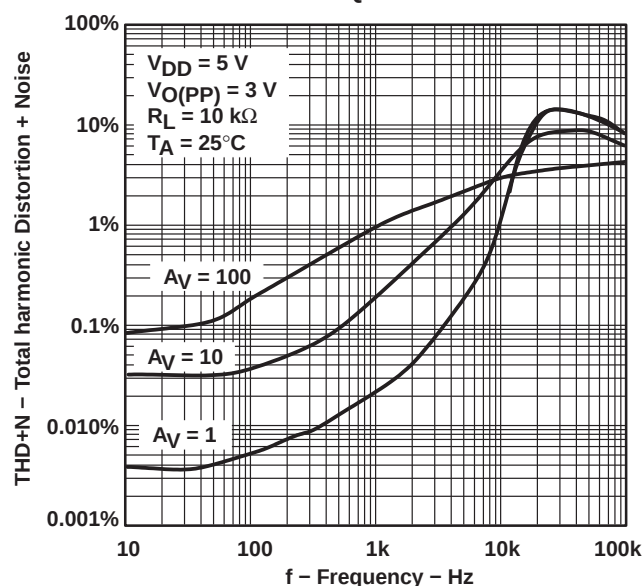


Figure 23

PHASE MARGIN
VS
LOAD CAPACITANCE



Figure 24

GAIN-BANDWIDTH PRODUCT
VS
SUPPLY VOLTAGE

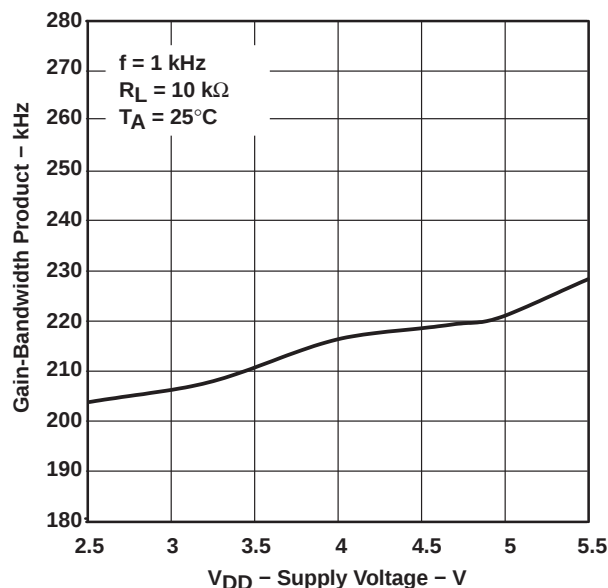


Figure 25

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 26



Figure 27

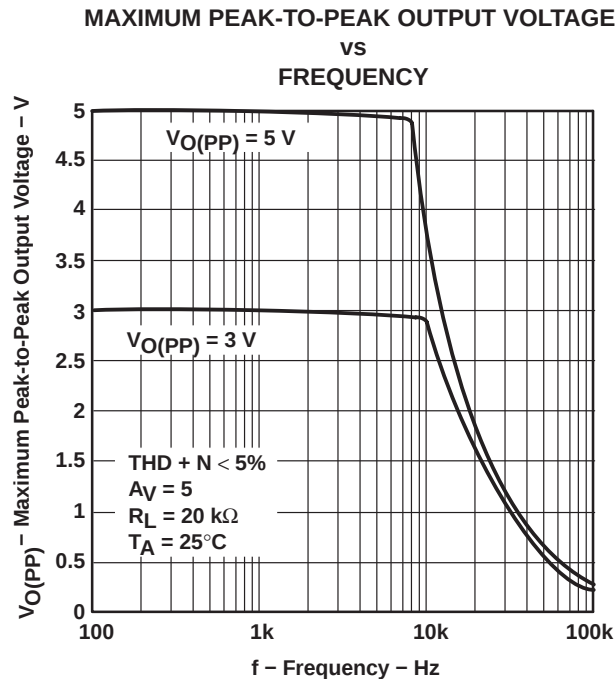


Figure 28

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

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TYPICAL CHARACTERISTICS

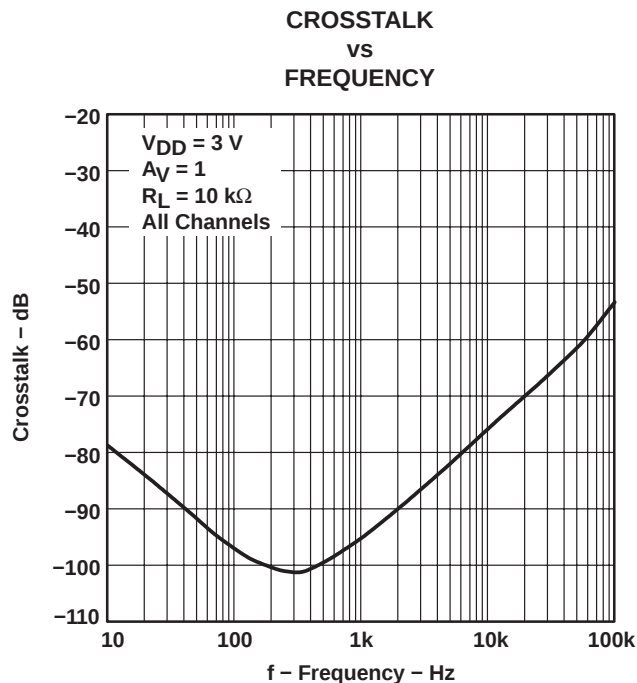


Figure 29

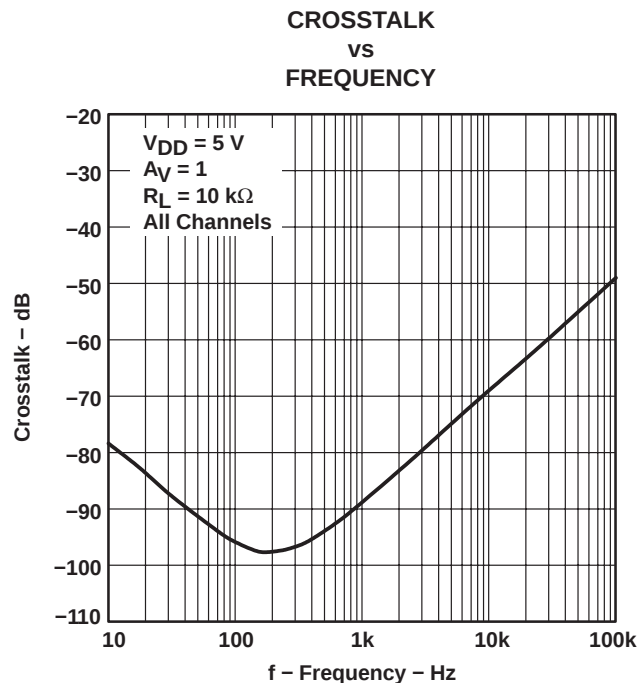


Figure 30

SMALL-SIGNAL FOLLOWER PULSE RESPONSE

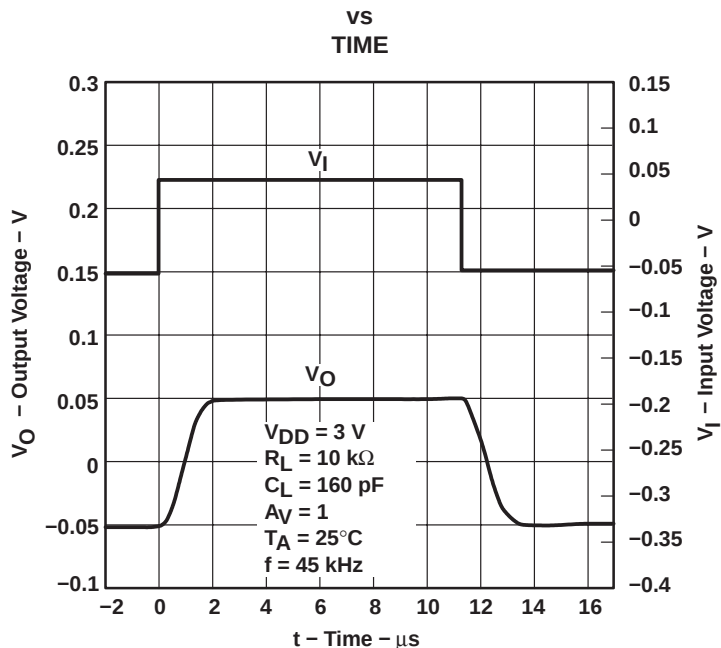


Figure 31

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

LARGE-SIGNAL FOLLOWER PULSE RESPONSE



Figure 32

SMALL-SIGNAL FOLLOWER PULSE RESPONSE



Figure 33

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

LARGE-SIGNAL FOLLOWER PULSE RESPONSE

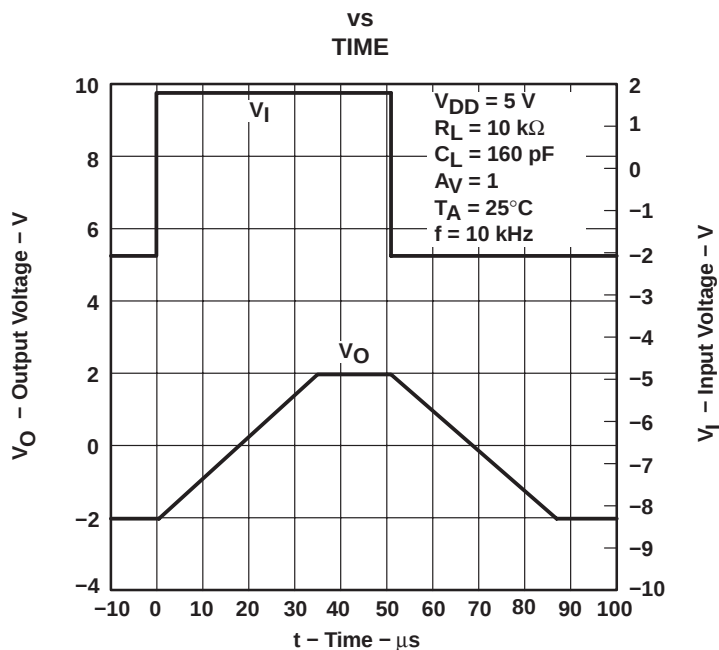


Figure 34

SHUTDOWN ON SUPPLY CURRENT



Figure 35



TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 36



Figure 37



TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

SHUTDOWN SUPPLY CURRENT AND SHUTDOWN PULSE vs TIME



Figure 38

SHUTDOWN SUPPLY CURRENT AND SHUTDOWN PULSE vs TIME

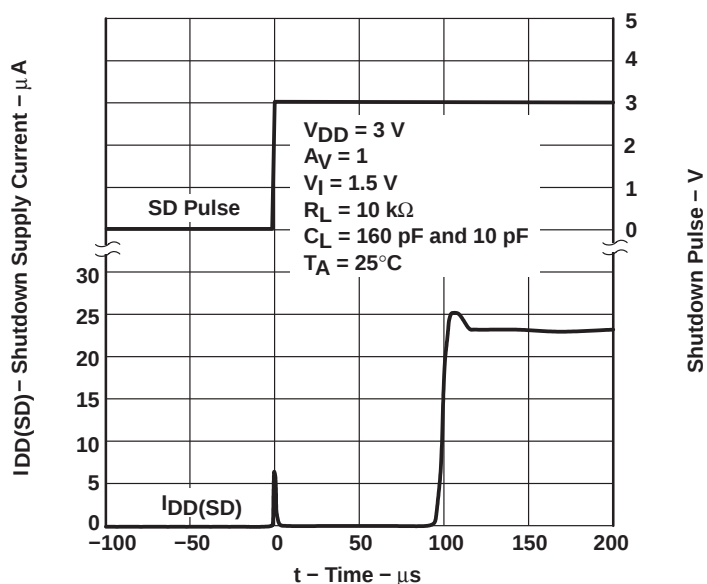


Figure 39

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

SHUTDOWN SUPPLY CURRENT AND SHUTDOWN PULSE
vs
TIME

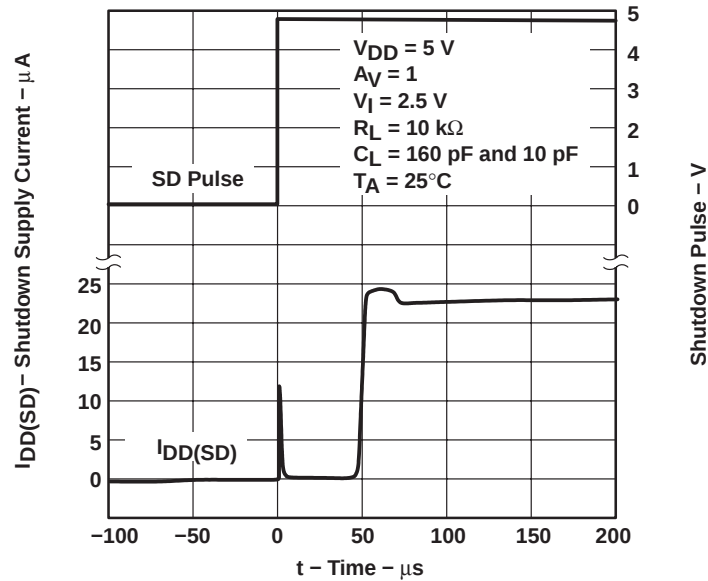


Figure 40

SHUTDOWN SUPPLY CURRENT AND SHUTDOWN PULSE
vs
TIME

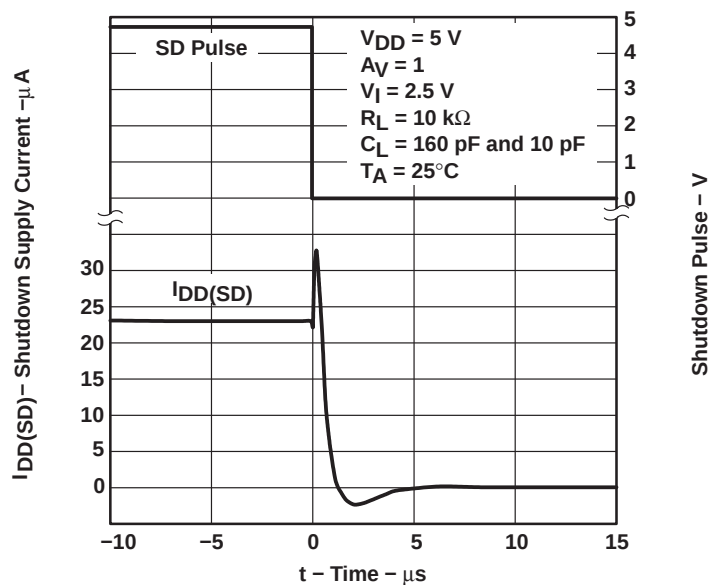


Figure 41



TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS

SHUTDOWN OFF PULSE RESPONSE

VS
TIME



Figure 42

SHUTDOWN OFF PULSE RESPONSE

VS
TIME



Figure 43

SHUTDOWN ON PULSE RESPONSE

VS
TIME



Figure 44

SHUTDOWN ON PULSE RESPONSE

VS
TIME



Figure 45

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA
FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT
OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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TYPICAL CHARACTERISTICS



Figure 46

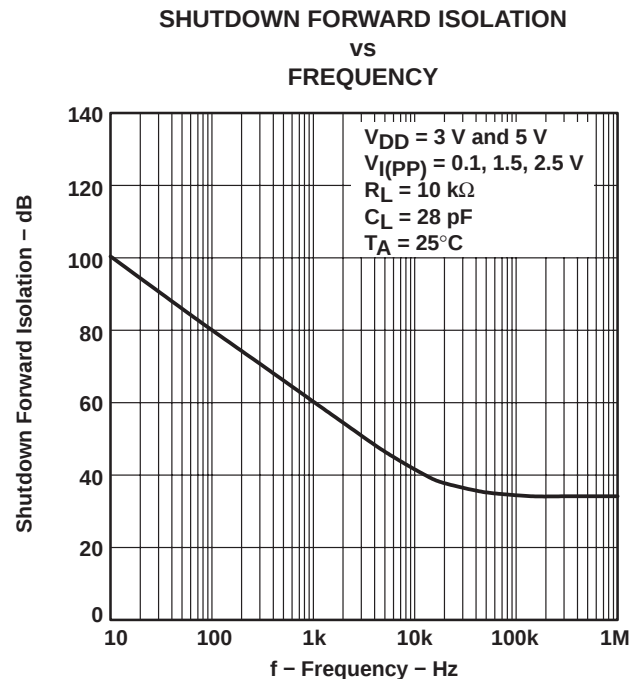


Figure 47

PARAMETER MEASUREMENT INFORMATION



Figure 48

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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APPLICATION INFORMATION

shutdown function

Three members of the TLV245x family (TLV2450/3/5) have a shutdown terminal for conserving battery life in portable applications. When the shutdown terminal is pulled to the voltage level on the GND terminal of the device, the supply current is reduced to 16 nA/channel, the amplifier is disabled, and the outputs are placed in a high impedance mode. To enable the amplifier, the shutdown terminal must be pulled high. The shutdown terminal should never be left floating. The shutdown terminal threshold is always referenced to the GND terminal of the device. Therefore, when operating the device with split supply voltages (e.g. ± 2.5 V), the shutdown terminal needs to be pulled to V_{DD-} (not system ground) to disable the operational amplifier.

The amplifier's output with a shutdown pulse is shown in Figures 42, 43, 44, and 45. The amplifier is powered with a single 5-V supply and configured as a noninverting configuration with a gain of 5. The amplifier turnon and turnoff times are measured from the 50% point of the shutdown pulse to the 50% point of the output waveform. The times for the single, dual, and quad are listed in the data tables.

Figures 46 and 47 show the amplifier's forward and reverse isolation in shutdown. The operational amplifier is powered by ± 1.35 -V supplies and configured as a voltage follower ($A_V = 1$). The isolation performance is plotted across frequency using 0.1- V_{PP} , 1.5- V_{PP} , and 2.5- V_{PP} input signals. During normal operation, the amplifier would not be able to handle a 2.5- V_{PP} input signal with a supply voltage of ± 1.35 V since it exceeds the common-mode input voltage range (V_{ICR}). However, this curve illustrates that the amplifier remains in shutdown even under a worst case scenario.

driving a capacitive load

When the amplifier is configured in this manner, capacitive loading directly on the output will decrease the device's phase margin leading to high frequency ringing or oscillations. Therefore, for capacitive loads of greater than 10 pF, it is recommended that a resistor be placed in series (R_{NULL}) with the output of the amplifier, as shown in Figure 49. A minimum value of 20 Ω should work well for most applications.

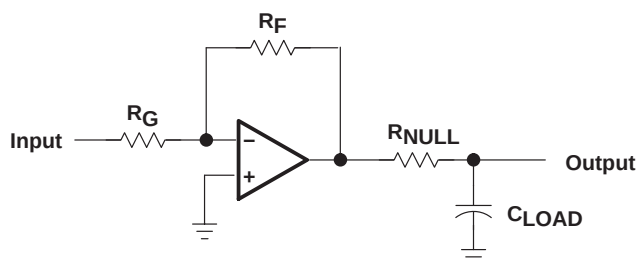


Figure 49. Driving a Capacitive Load

APPLICATION INFORMATION

offset voltage

The output offset voltage, (V_{OO}) is the sum of the input offset voltage (V_{IO}) and both input bias currents (I_{IB}) times the corresponding gains. The following schematic and formula can be used to calculate the output offset voltage:



Figure 50. Output Offset Voltage Model

general configurations

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to accomplish this is to place an RC filter at the noninverting terminal of the amplifier (see Figure 51).

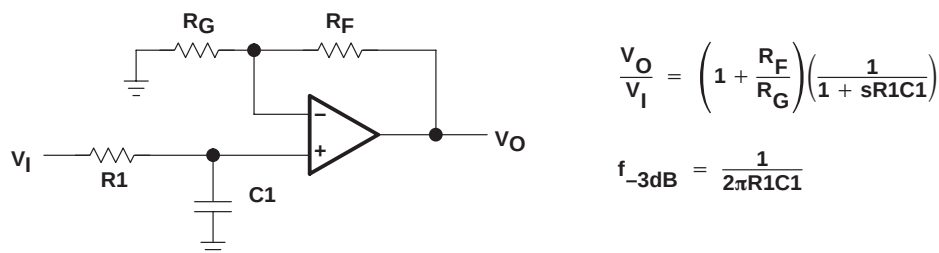


Figure 51. Single-Pole Low-Pass Filter

If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to do this can result in phase shift of the amplifier.



Figure 52. 2-Pole Low-Pass Sallen-Key Filter

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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APPLICATION INFORMATION

general power dissipation considerations

For a given θ_{JA} , the maximum power dissipation is shown in Figure 53 and is calculated by the following formula:

$$P_D = \left(\frac{T_{MAX} - T_A}{\theta_{JA}} \right)$$

Where:

P_D = Maximum power dissipation of TLV245x IC (watts)

T_{MAX} = Absolute maximum junction temperature (150°C)

T_A = Free-ambient air temperature (°C)

$\theta_{JA} = \theta_{JC} + \theta_{CA}$

θ_{JC} = Thermal coefficient from junction to case

θ_{CA} = Thermal coefficient from case to ambient air (°C/W)



NOTE A: Results are with no air flow and using JEDEC Standard Low-K test PCB.

Figure 53. Maximum Power Dissipation vs Free-Air Temperature

TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT OPERATIONAL AMPLIFIERS WITH SHUTDOWN

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APPLICATION INFORMATION

macromodel information

Macromodel information provided was derived using Microsim *Parts*™, the model generation software used with Microsim *PSpice*™. The Boyle macromodel (see Note 1) and subcircuit in Figure 54 are generated using the TLV245x typical electrical and operating characteristics at $T_A = 25^\circ\text{C}$. Using this information, output simulations of the following key parameters can be generated to a tolerance of 20% (in most cases):

- Maximum positive output voltage swing
- Maximum negative output voltage swing
- Slew rate
- Quiescent power dissipation
- Input bias current
- Open-loop voltage amplification
- Unity-gain frequency
- Common-mode rejection ratio
- Phase margin
- DC output resistance
- AC output resistance
- Short-circuit output current limit

NOTE 1: G. R. Boyle, B. M. Cohn, D. O. Pederson, and J. E. Solomon, "Macromodeling of Integrated Circuit Operational Amplifiers," *IEEE Journal of Solid-State Circuits*, SC-9, 353 (1974).

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TLV2450, TLV2451, TLV2452, TLV2453, TLV2454, TLV2455, TLV245xA

FAMILY OF 23- μ A 220-kHz RAIL-TO-RAIL INPUT/OUTPUT

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APPLICATION INFORMATION



* AMP_TLV2450-X operational amplifier "macromodel" subcircuit
 * created using Parts release 8.0 on 10/12/98 at 11:06
 * Parts is a MicroSim product.

* connections:

noninverting input
 |
 inverting input
 |
 positive power supply
 |
 negative power supply
 |
 output

.subckt AMP_TLV2450-X 1 2 3 4 5

*

C1	11	12	354.48E-15
C2	6	7	7.5000E-12
CEE	10	99	42.237E-15
DC	5	53	dy
DE	54	5	dy
DLP	90	91	dx
DLN	92	90	dx
DP	4	3	dx
EGND	99	0	poly(2) (3,0) (4,0) 0 .5 .5
FB	7	99	poly(5) vb vc ve vlp vln 0
+ 207.31E6 -1E3 1E3 210E6 -210E6			
GA	6	0	11 12 15.254E-6
GCM	0	6	10 99 48.237E-12

IEE	10	4	dc	938.61E-9
HLIM	90	0	vlim	1K
Q1	11	2	13	qx1
Q2	12	1	14	qx2
R2	6	9	100.00E3	
RC1	3	11	65.557E3	
RC2	3	12	65.557E3	
RE1	13	10	10.367E3	
RE2	14	10	10.367E3	
REE	10	99	213.08E6	
RO1	8	5	10	
RO2	7	99	10	
RP	3	4	147.06	
VB	9	0	dc	0
VC	3	53	dc	.82
VE	54	4	dc	.82
VLIM	7	8	dc	0
VLP	91	0	dc	38
VLN	0	92	dc	38
.model dx D(Is=800.00E-18)				
.model dy D(Is=800.00E-18 Rs=1m Cjo=10p)				
.model qx1 NPN(Is=800.00E-18 Bf=843.08)				
.model qx2 NPN(Is=800.0000E-18 Bf=843.08)				
.ends				

Figure 54. Boyle Macromodel and Subcircuit

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2450AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2450AI
TLV2450AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2450AI
TLV2450AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2450AI
TLV2450AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2450AI
TLV2450CDBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	VAQC
TLV2450CDBVR.A	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	VAQC
TLV2450CDBVT	Obsolete	Production	SOT-23 (DBV) 6	-	-	Call TI	Call TI	0 to 70	VAQC
TLV2450CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2450C
TLV2450CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2450C
TLV2450ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2450I
TLV2450ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2450I
TLV2450IDBVR	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VAQI
TLV2450IDBVR.A	Active	Production	SOT-23 (DBV) 6	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VAQI
TLV2450IDBVT	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VAQI
TLV2450IDBVT.A	Active	Production	SOT-23 (DBV) 6	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VAQI
TLV2451AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2451AI
TLV2451AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2451AI
TLV2451AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2451AI
TLV2451AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2451AI
TLV2451CD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2451C
TLV2451CD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2451C
TLV2451CDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	VARC
TLV2451CDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	VARC
TLV2451CDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	VARC
TLV2451CDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	0 to 70	VARC
TLV2451CDG4	Active	Production	SOIC (D) 8	75 TUBE	-	Call TI	Call TI	0 to 70	
TLV2451CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2451C
TLV2451CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2451C
TLV2451CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2451C

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2451CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2451C
TLV2451IDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VARI
TLV2451IDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VARI
TLV2451IDBVT	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	VARI
TLV2451IDBVT.A	Active	Production	SOT-23 (DBV) 5	250 SMALL T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	VARI
TLV2451IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2451I
TLV2451IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2451I
TLV2451IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2451I
TLV2451IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2451I
TLV2452AID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452AI
TLV2452AID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452AI
TLV2452AIDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452AI
TLV2452AIDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452AI
TLV2452AIP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2452AI
TLV2452AIP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2452AI
TLV2452CD	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2452C
TLV2452CD.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2452C
TLV2452CDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ABI
TLV2452CDGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABI
TLV2452CDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	0 to 70	ABI
TLV2452CDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABI
TLV2452CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2452C
TLV2452CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	2452C
TLV2452ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452I
TLV2452ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452I
TLV2452IDGK	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ABJ
TLV2452IDGK.A	Active	Production	VSSOP (DGK) 8	80 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABJ
TLV2452IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	ABJ
TLV2452IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABJ
TLV2452IDGKRG4	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TLV2452IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2452IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2452I
TLV2452IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2452IP
TLV2452IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2452IP
TLV2453CDGSR	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABK
TLV2453CDGSR.A	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	ABK
TLV2453CDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2453C
TLV2453CDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TLV2453C
TLV2453IDGSR	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABL
TLV2453IDGSR.A	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	ABL
TLV2454AID	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454AI
TLV2454AID.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454AI
TLV2454AIDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454AI
TLV2454AIDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454AI
TLV2454AIN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2454AI
TLV2454AIN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2454AI
TLV2454AIPW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-	TY2454A
TLV2454AIPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454A
TLV2454AIPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454A
TLV2454CD	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	0 to 70	2454C
TLV2454CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2454C
TLV2454CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TLV2454C
TLV2454CPW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2454
TLV2454CPW.A	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2454
TLV2454CPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2454
TLV2454CPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TV2454
TLV2454ID	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454I
TLV2454ID.A	Active	Production	SOIC (D) 14	50 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454I
TLV2454IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454I
TLV2454IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2454I
TLV2454IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2454I
TLV2454IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2454I

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2454IPW	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454
TLV2454IPW.A	Active	Production	TSSOP (PW) 14	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454
TLV2454IPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454
TLV2454IPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2454
TLV2455AID	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455AI
TLV2455AID.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455AI
TLV2455AIDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455AI
TLV2455AIDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455AI
TLV2455AIN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2455AI
TLV2455AIN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TLV2455AI
TLV2455AIPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2455A
TLV2455AIPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2455A
TLV2455IDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455I
TLV2455IDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TLV2455I
TLV2455IPW	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2455
TLV2455IPW.A	Active	Production	TSSOP (PW) 16	90 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TY2455

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2450AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2450CDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2450IDBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2450IDBVT	SOT-23	DBV	6	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2451AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2451CDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2451CDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2451CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2451IDBVR	SOT-23	DBV	5	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2451IDBVT	SOT-23	DBV	5	250	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TLV2451IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2452AIDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2452CDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2452CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2452IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2452IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2453CDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2453CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2453IDGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2454AIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2454AIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2454CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2454IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TLV2454IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2455AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TLV2455AIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TLV2455IDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

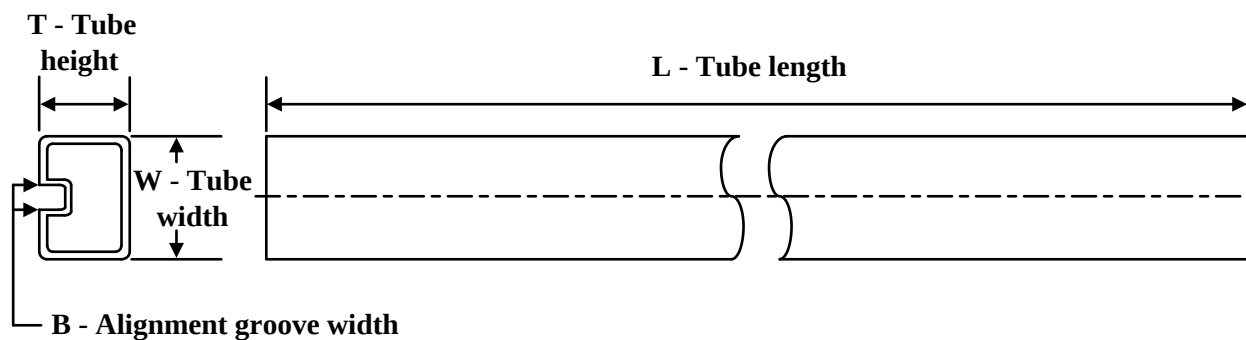


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2450AIDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2450CDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TLV2450IDBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TLV2450IDBVT	SOT-23	DBV	6	250	210.0	185.0	35.0
TLV2451AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2451CDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV2451CDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TLV2451CDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2451IDBVR	SOT-23	DBV	5	3000	210.0	185.0	35.0
TLV2451IDBVT	SOT-23	DBV	5	250	210.0	185.0	35.0
TLV2451IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2452AIDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2452CDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2452CDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2452IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2452IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2453CDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2453CDR	SOIC	D	14	2500	350.0	350.0	43.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2453IDGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0
TLV2454AIDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2454AIPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2454CPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2454IDR	SOIC	D	14	2500	350.0	350.0	43.0
TLV2454IPWR	TSSOP	PW	14	2000	353.0	353.0	32.0
TLV2455AIDR	SOIC	D	16	2500	350.0	350.0	43.0
TLV2455AIPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
TLV2455IDR	SOIC	D	16	2500	350.0	350.0	43.0

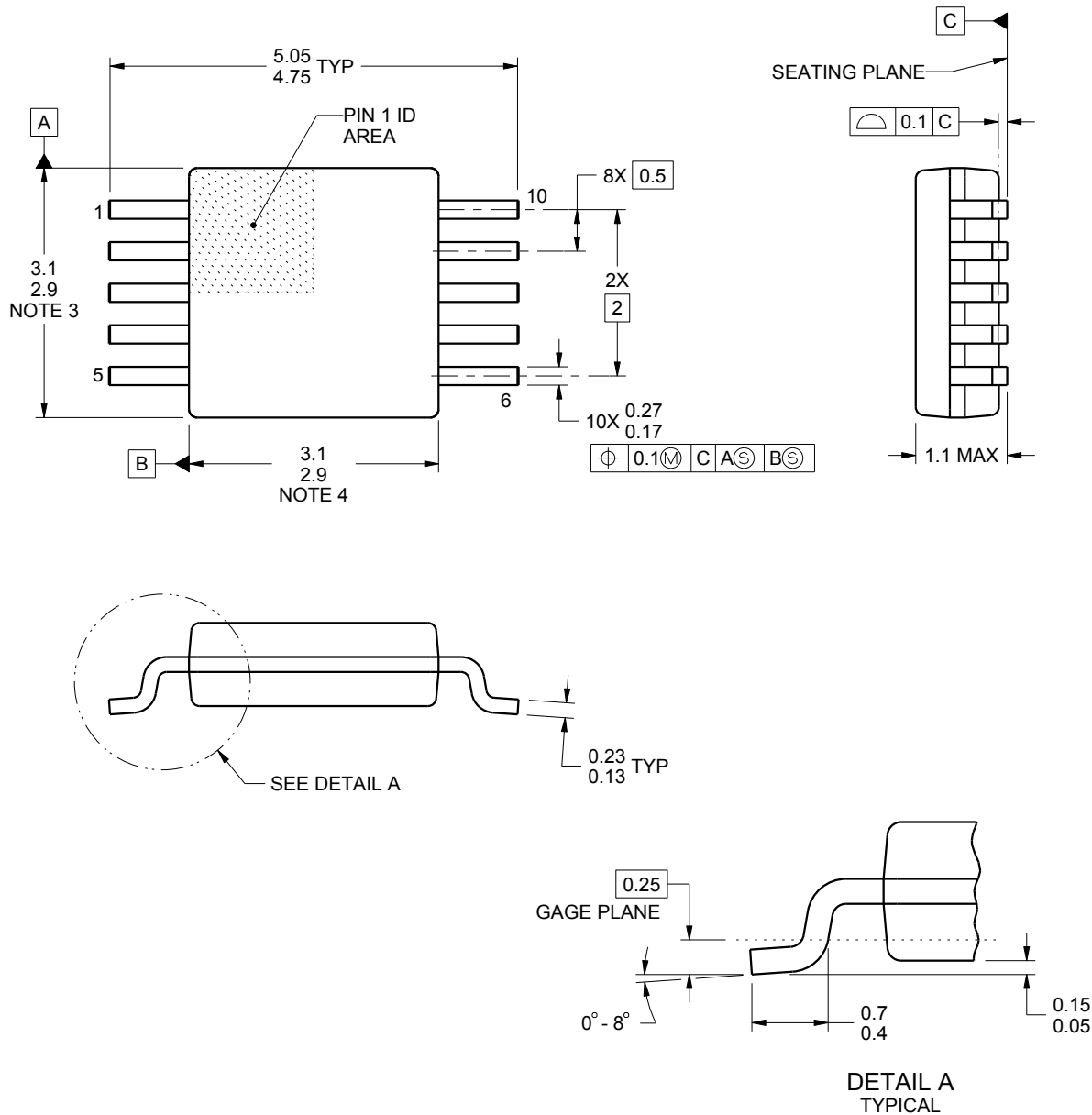
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2450AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2450AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2450CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2450CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2450ID	D	SOIC	8	75	507	8	3940	4.32
TLV2450ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2451AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2451AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2451CD	D	SOIC	8	75	507	8	3940	4.32
TLV2451CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2451CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2451CD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2451CP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2451CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2451IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2451IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2452AID	D	SOIC	8	75	507	8	3940	4.32
TLV2452AID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452AID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2452AID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452AIP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2452AIP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2452CD	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452CD	D	SOIC	8	75	507	8	3940	4.32
TLV2452CD.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452CD.A	D	SOIC	8	75	507	8	3940	4.32
TLV2452CDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2452CDGK.A	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2452ID	D	SOIC	8	75	507	8	3940	4.32

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TLV2452ID	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452ID.A	D	SOIC	8	75	505.46	6.76	3810	4
TLV2452ID.A	D	SOIC	8	75	507	8	3940	4.32
TLV2452IDGK	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2452IDGK.A	DGK	VSSOP	8	80	330	6.55	500	2.88
TLV2452IP	P	PDIP	8	50	506	13.97	11230	4.32
TLV2452IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TLV2454AID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2454AID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLV2454AIN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454AIN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454CN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454CPW	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2454CPW.A	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2454ID	D	SOIC	14	50	505.46	6.76	3810	4
TLV2454ID.A	D	SOIC	14	50	505.46	6.76	3810	4
TLV2454IN	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TLV2454IPW	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2454IPW.A	PW	TSSOP	14	90	530	10.2	3600	3.5
TLV2455AID	D	SOIC	16	40	505.46	6.76	3810	4
TLV2455AID.A	D	SOIC	16	40	505.46	6.76	3810	4
TLV2455AIN	N	PDIP	16	25	506	13.97	11230	4.32
TLV2455AIN.A	N	PDIP	16	25	506	13.97	11230	4.32
TLV2455IPW	PW	TSSOP	16	90	530	10.2	3600	3.5
TLV2455IPW.A	PW	TSSOP	16	90	530	10.2	3600	3.5



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NOTES:

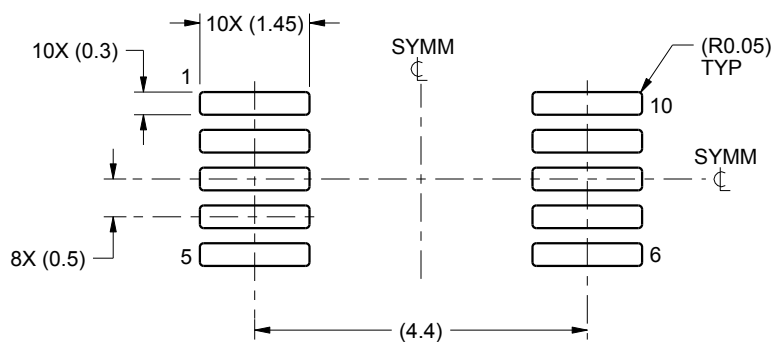
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187, variation BA.

EXAMPLE BOARD LAYOUT

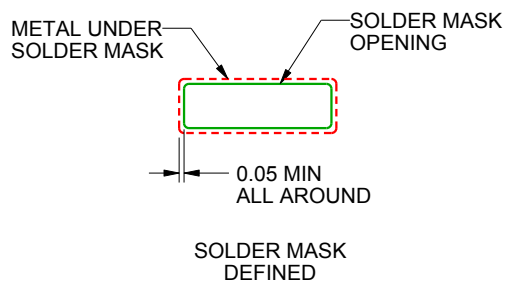
DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221984/A 05/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

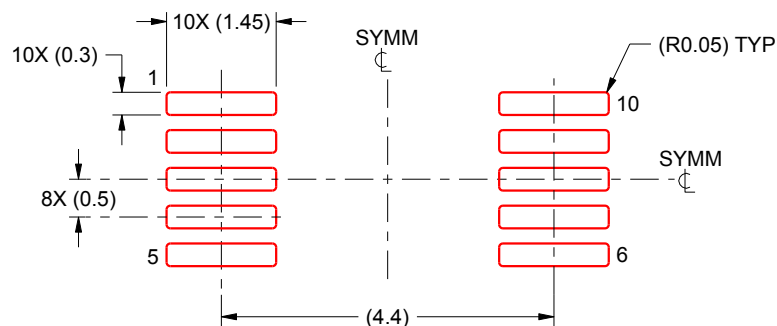
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGS0010A

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

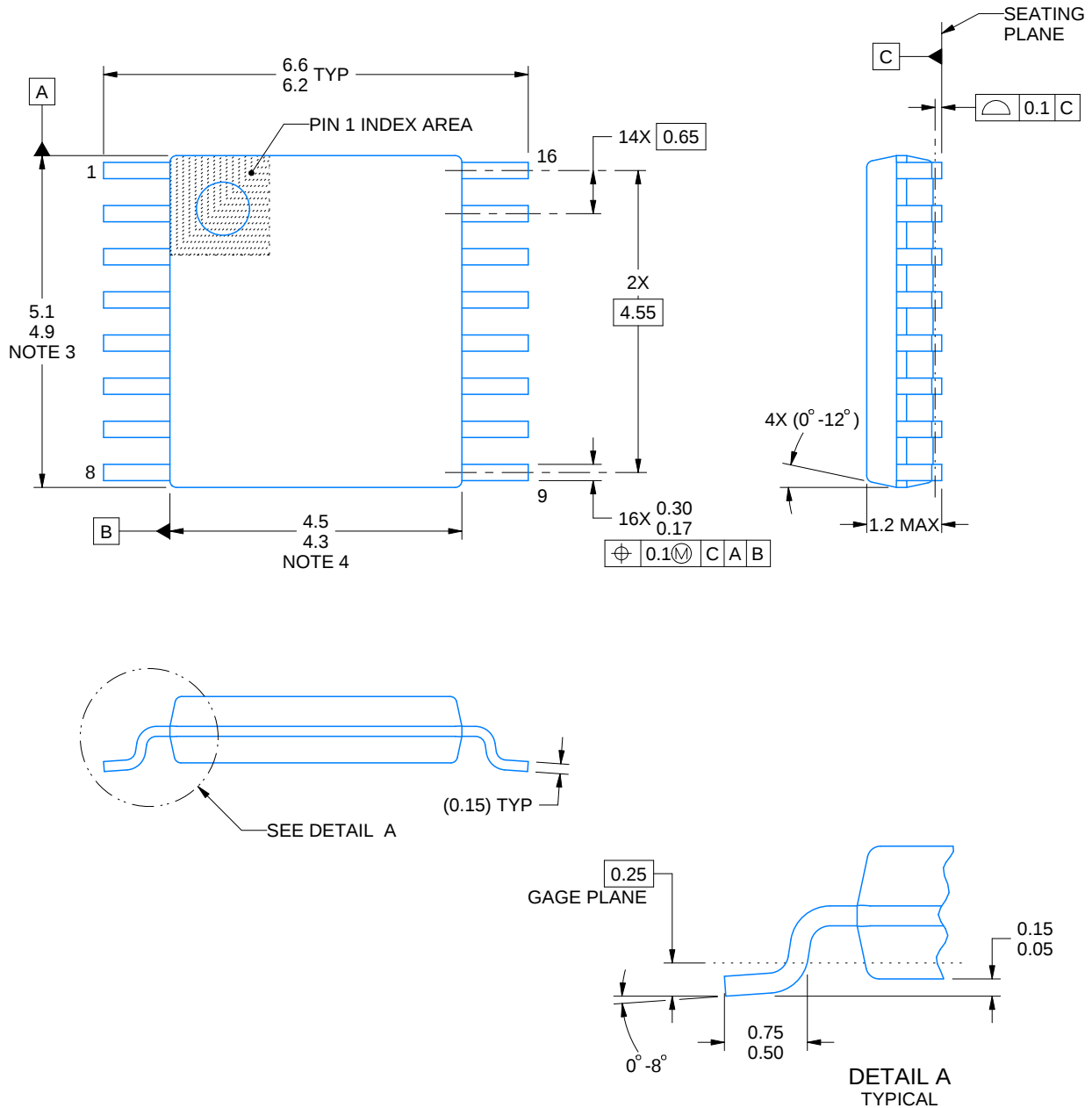
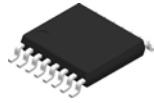


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221984/A 05/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



4220204/B 12/2023

NOTES:

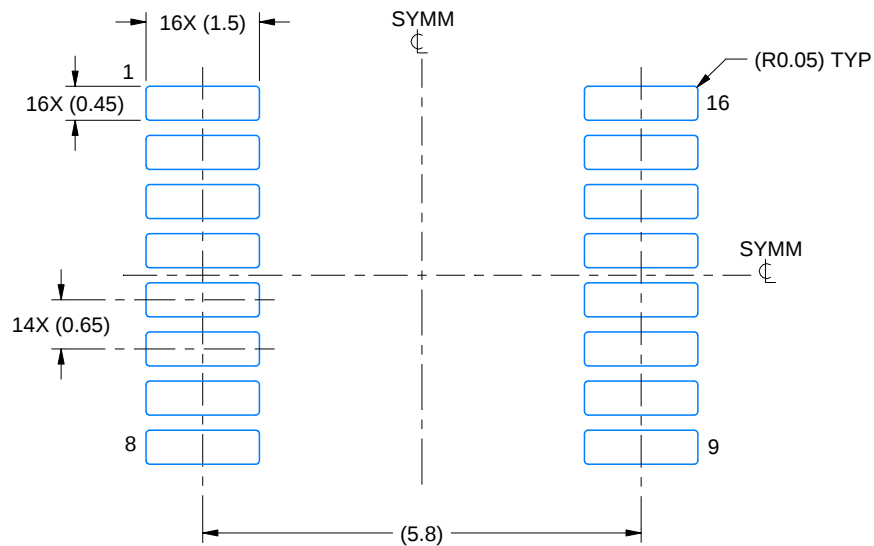
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

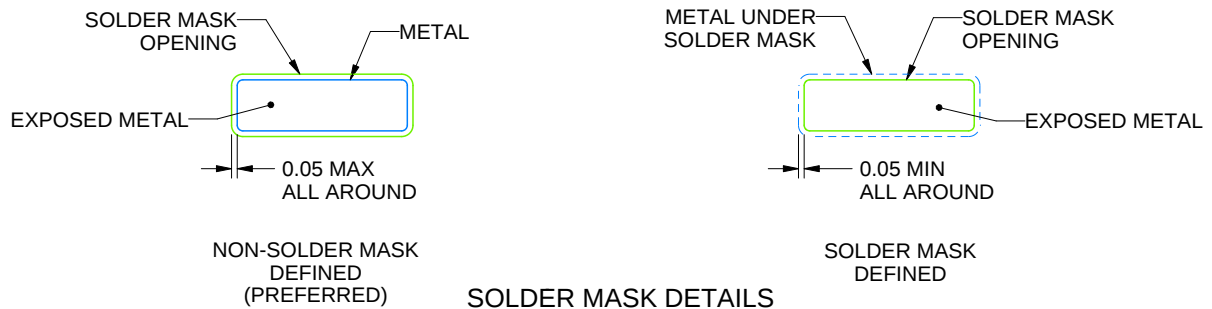
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

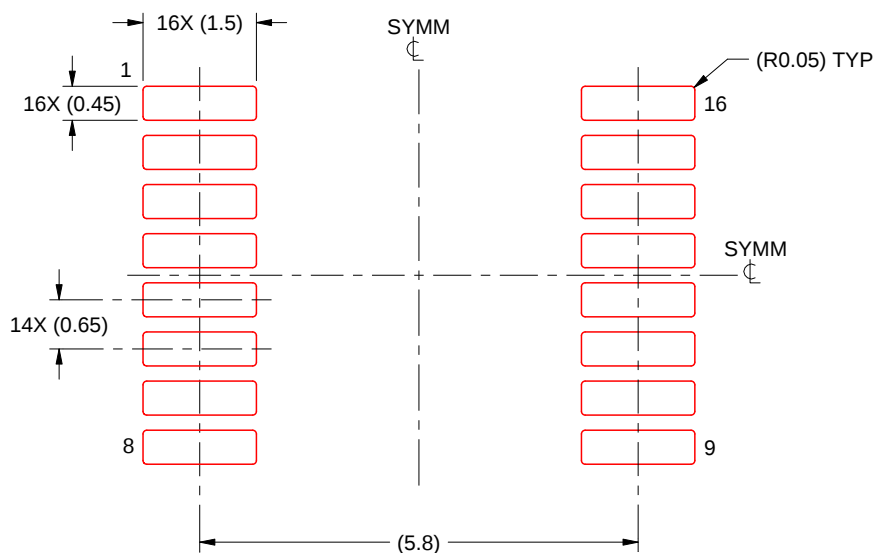
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

NOTES: (continued)

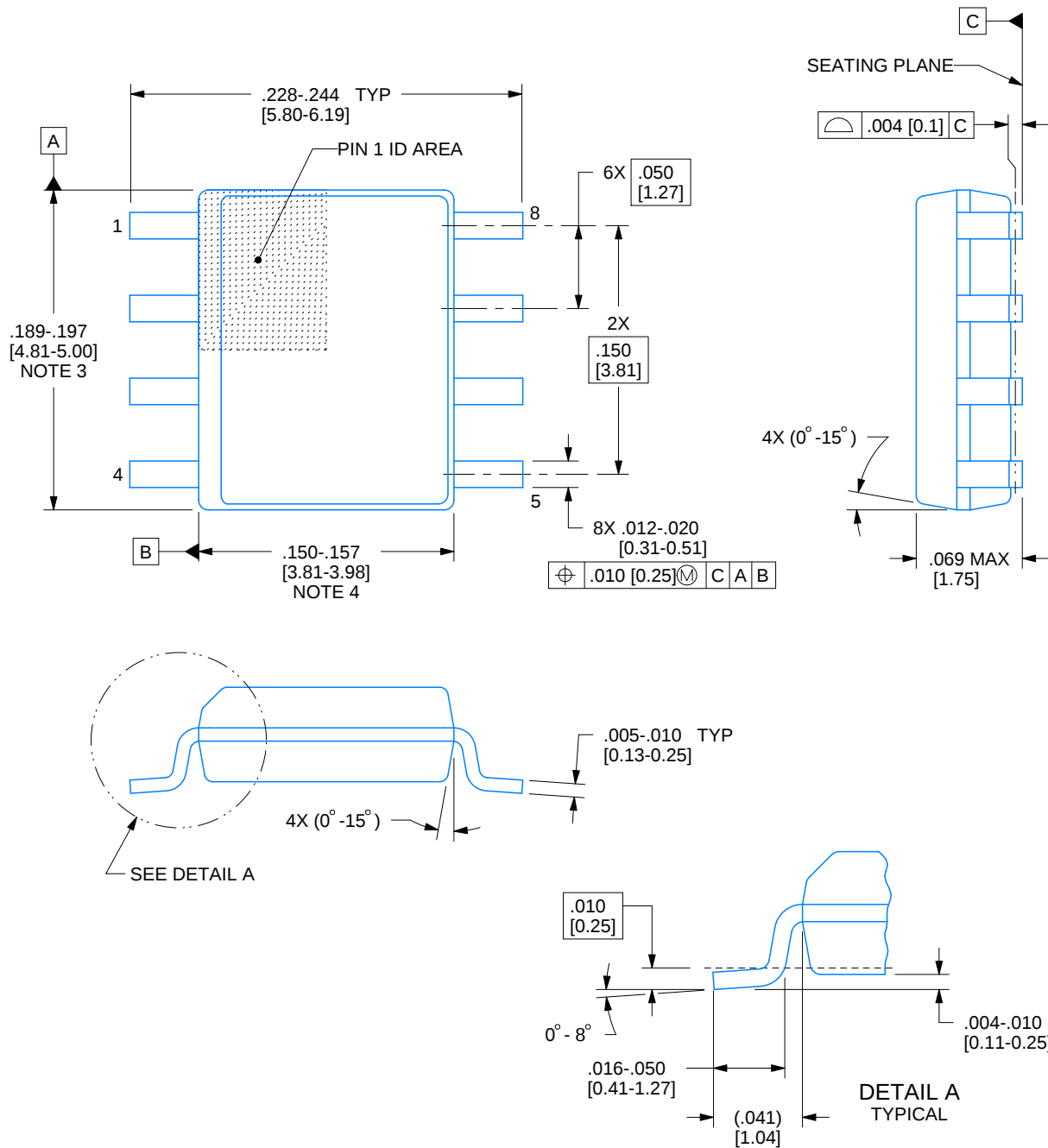
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

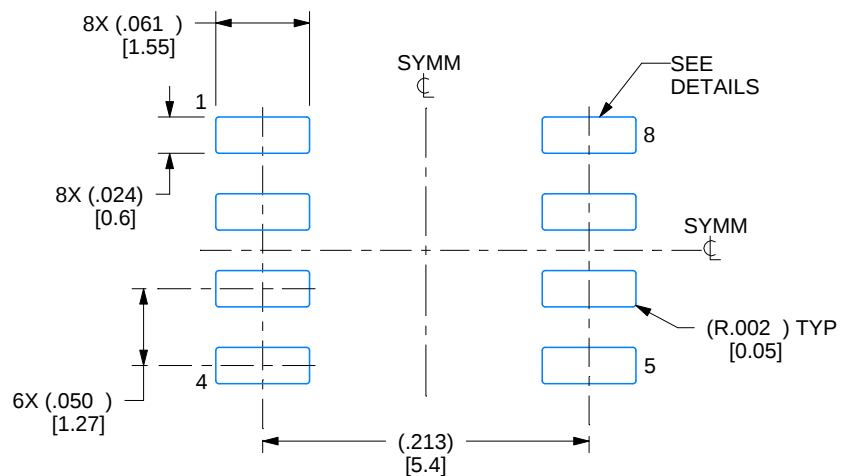
NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

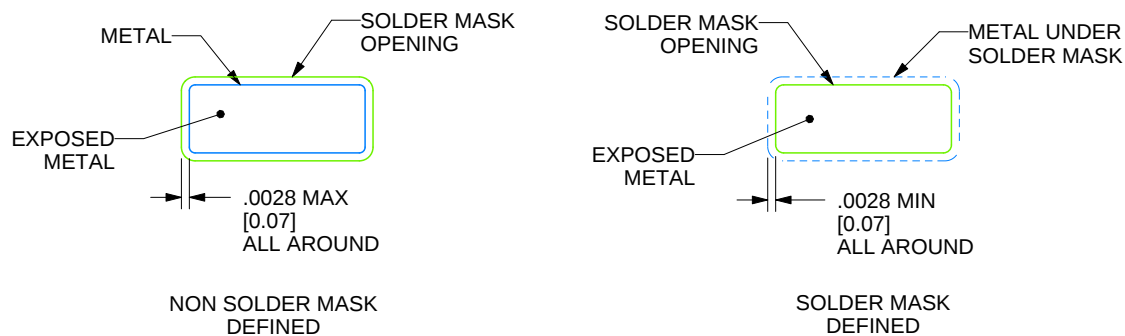
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

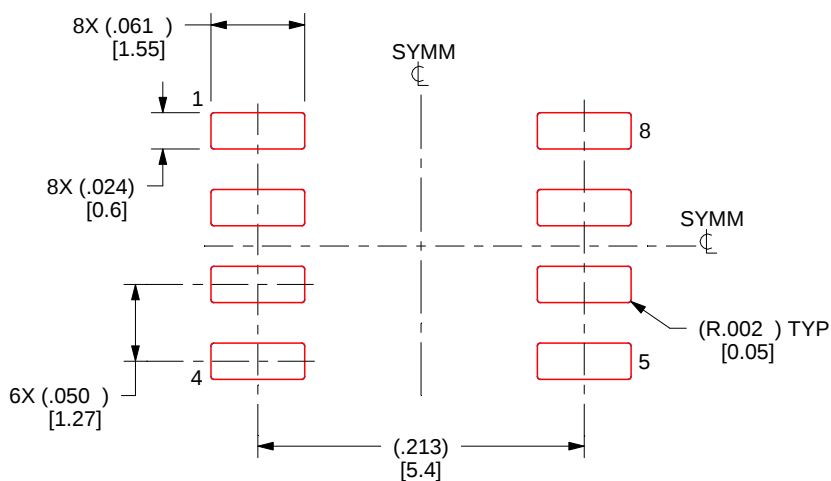
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE

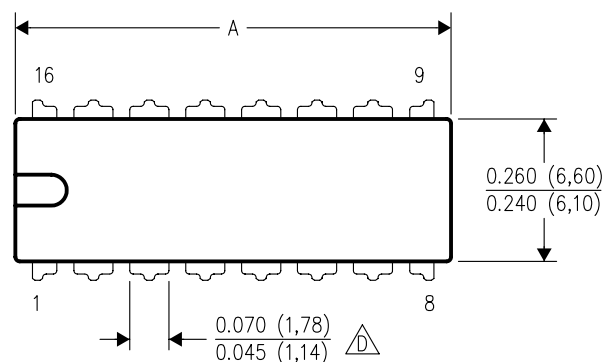


- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

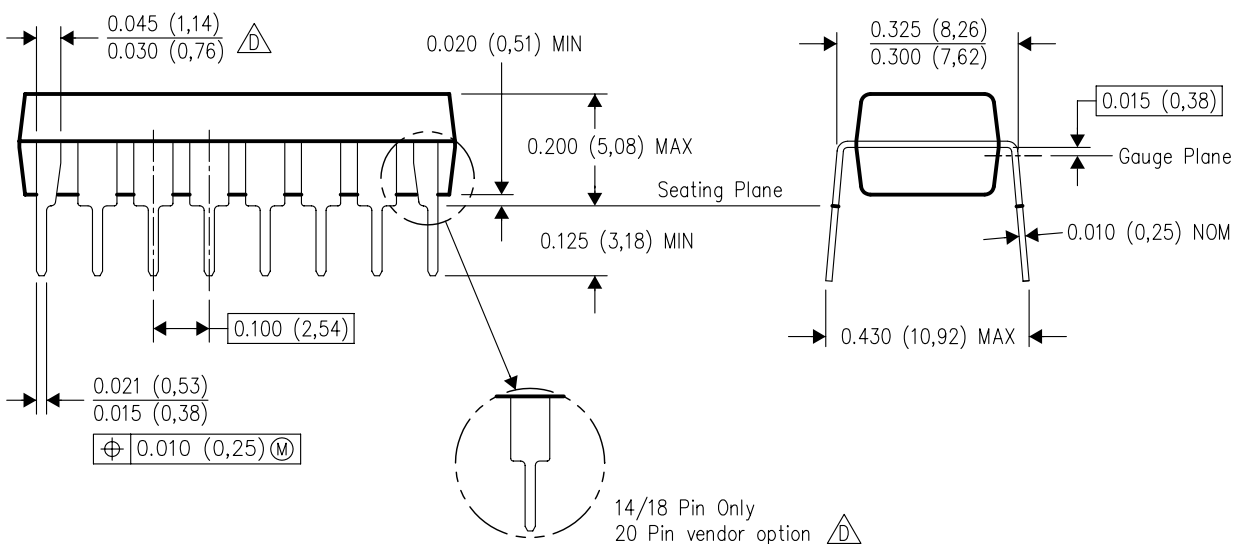
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
 Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



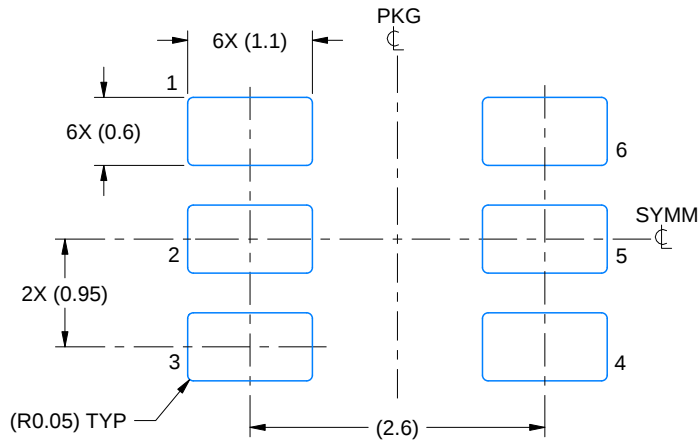
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

EXAMPLE BOARD LAYOUT

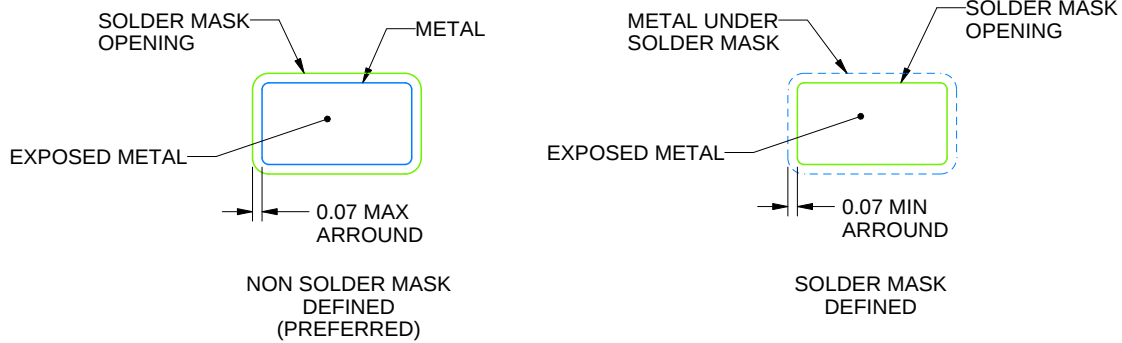
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

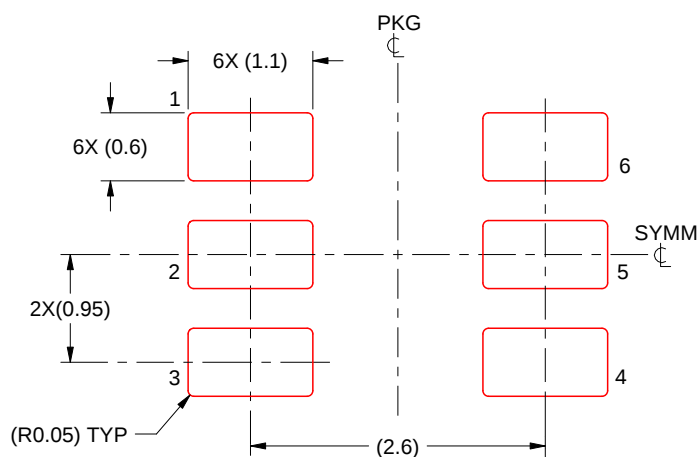
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

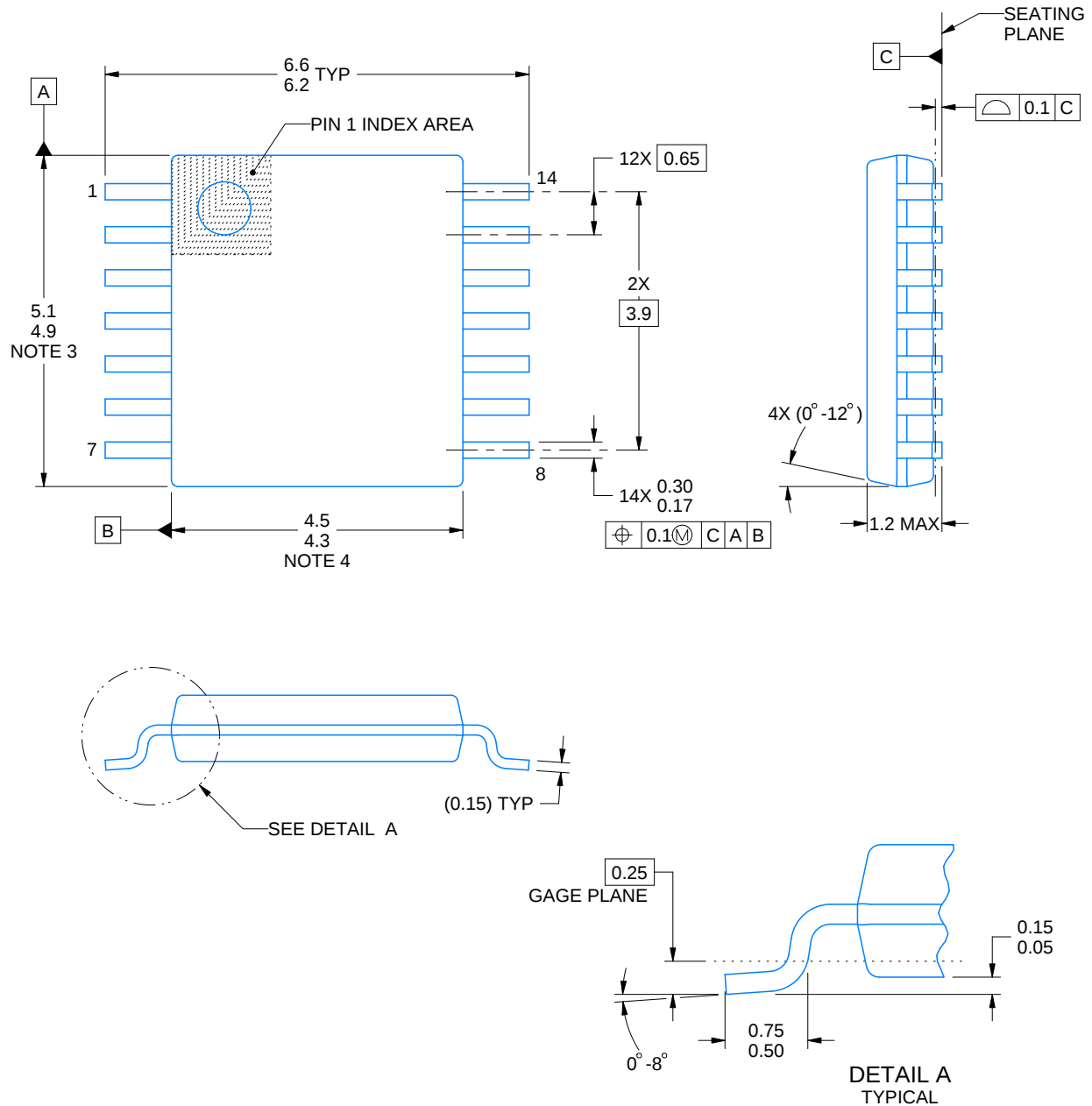
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

PW0014A

PACKAGE OUTLINE

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



4220202/B 12/2023

NOTES:

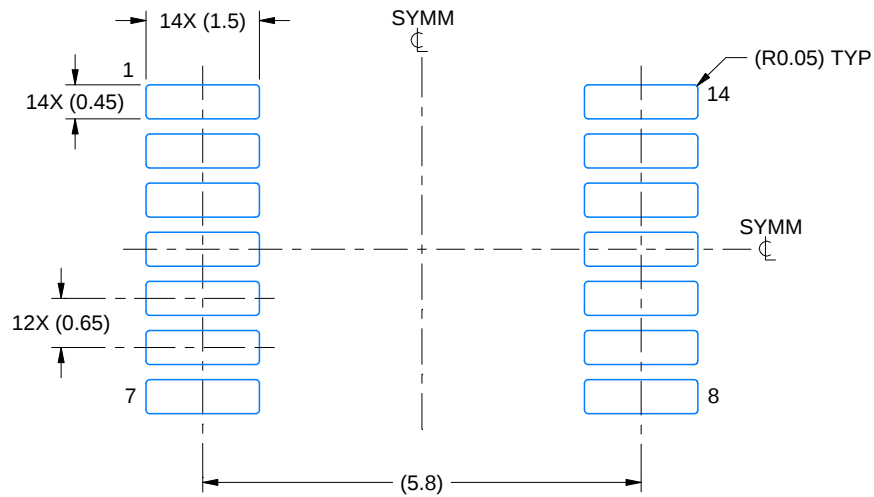
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

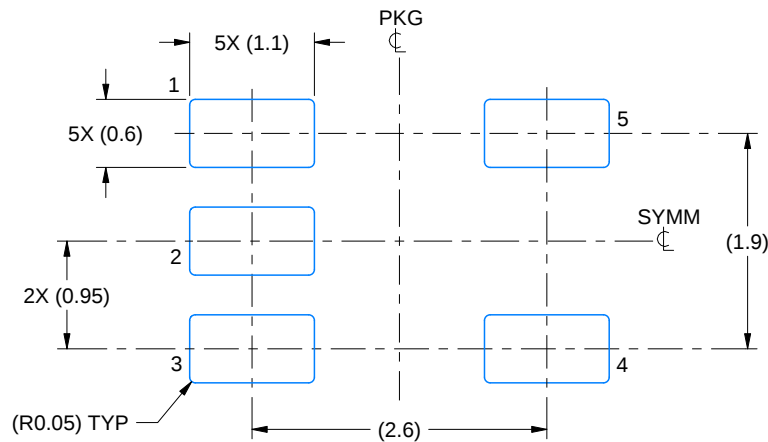
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

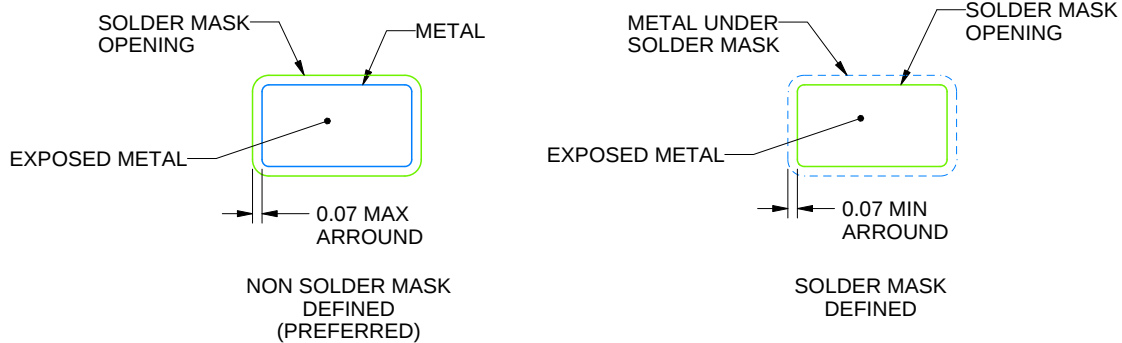
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

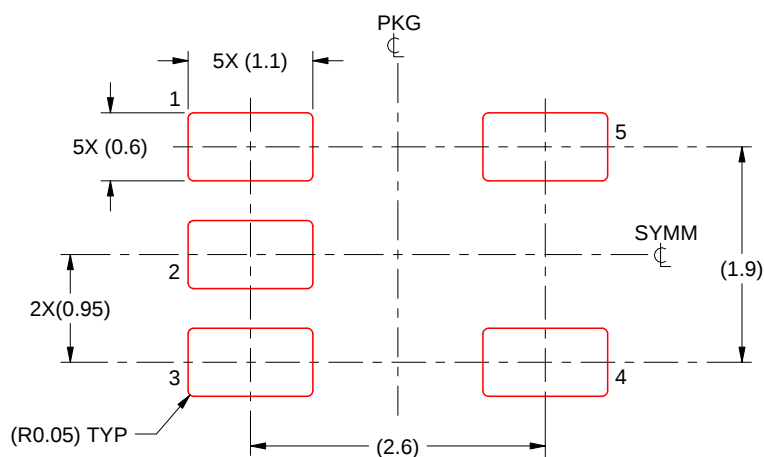
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

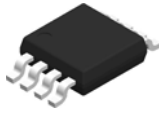


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

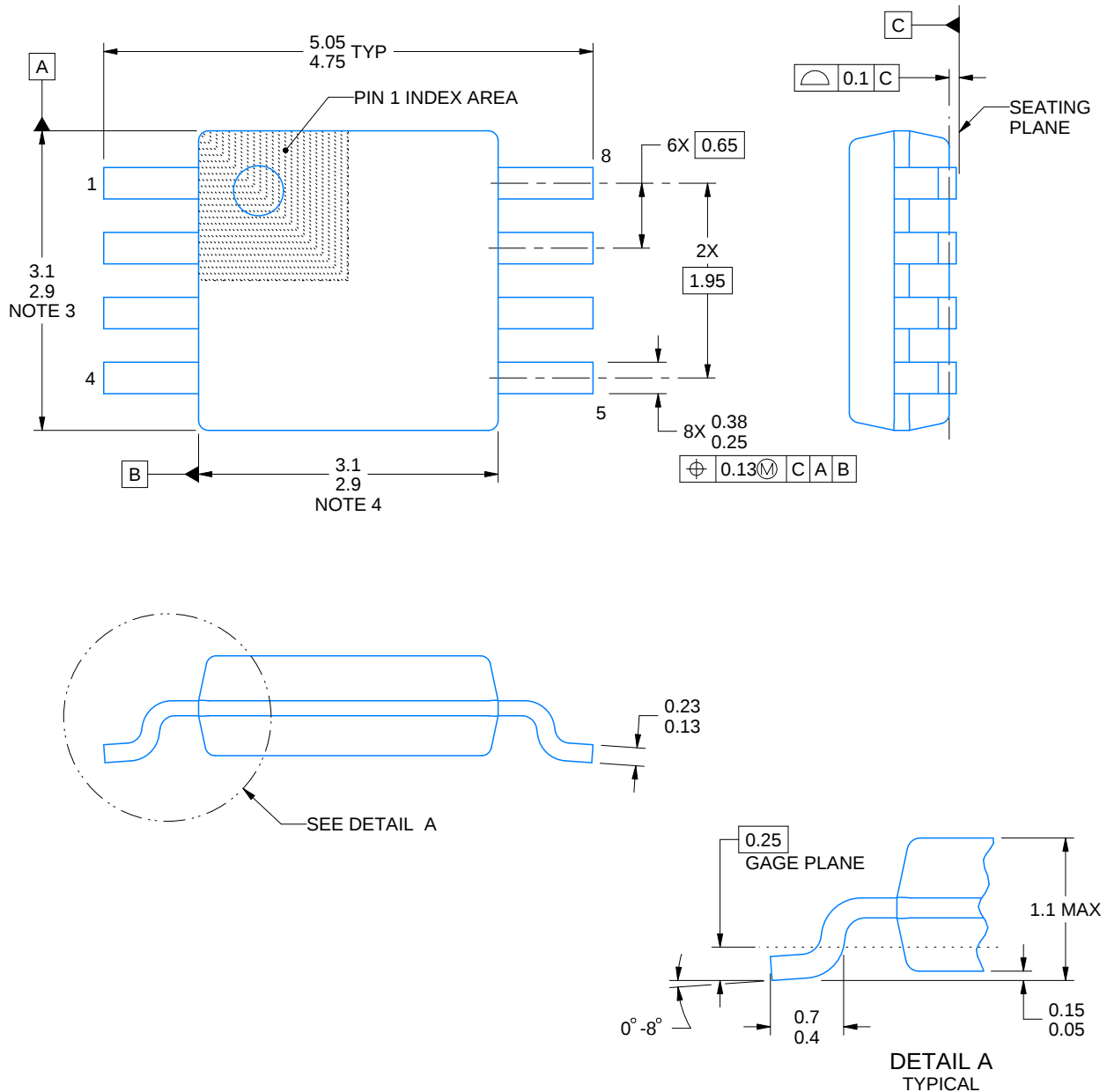
4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DGK0008A**PACKAGE OUTLINE****VSSOP - 1.1 mm max height**

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

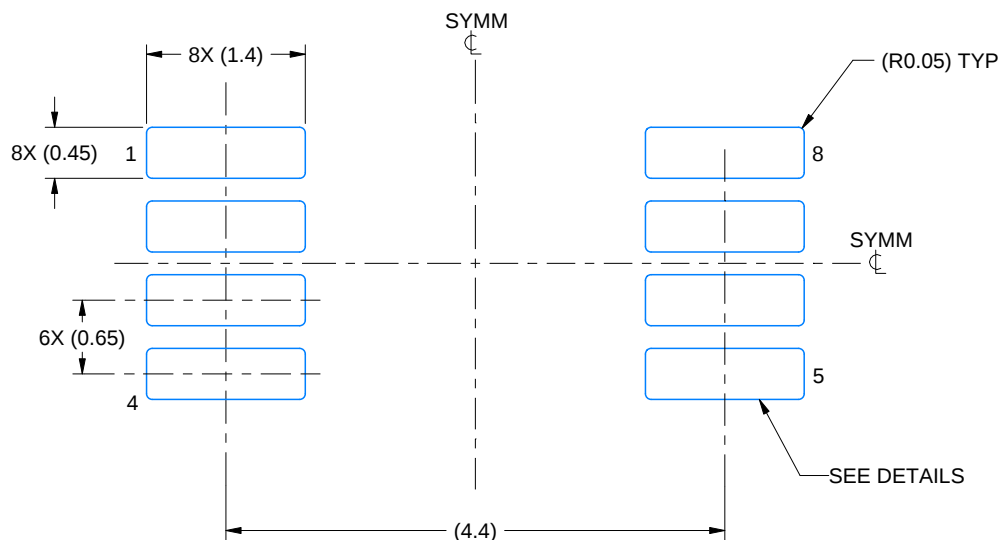
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

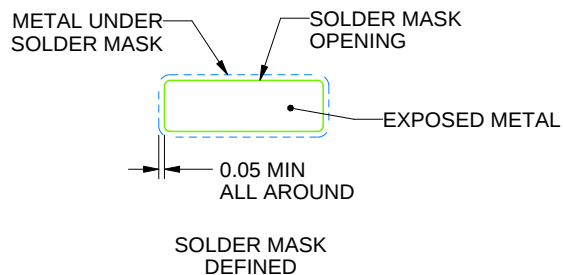
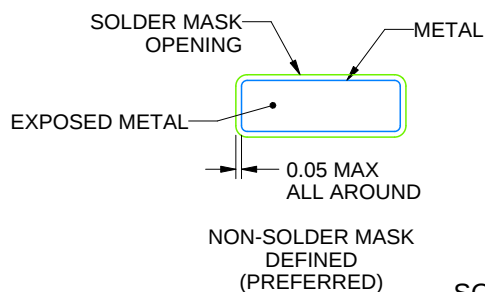
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

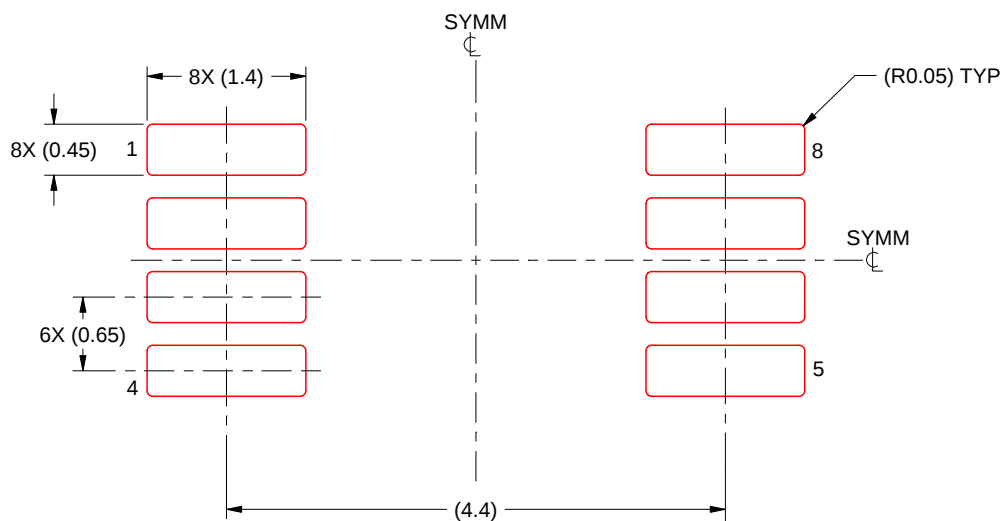
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

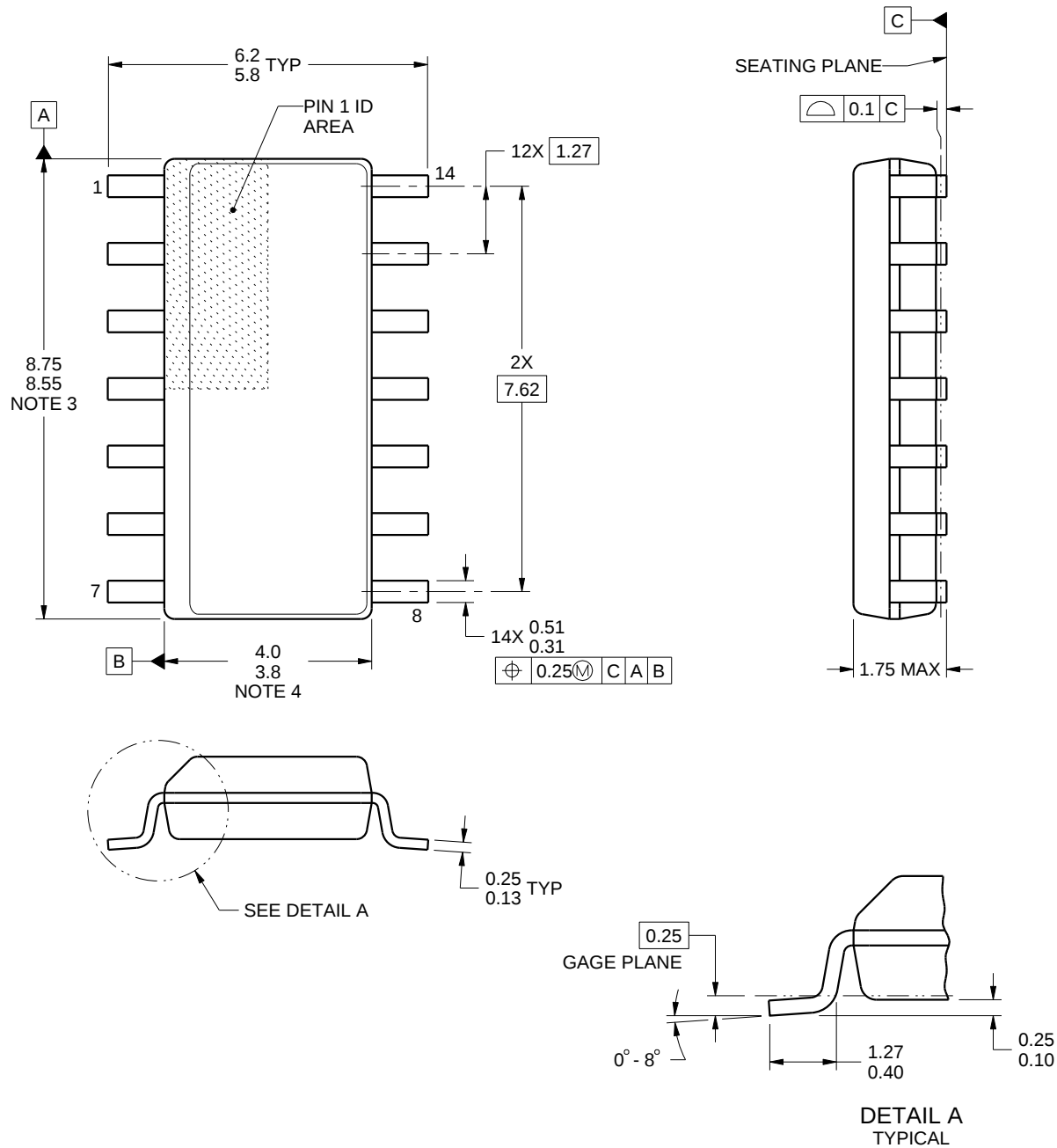
11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

D0014A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

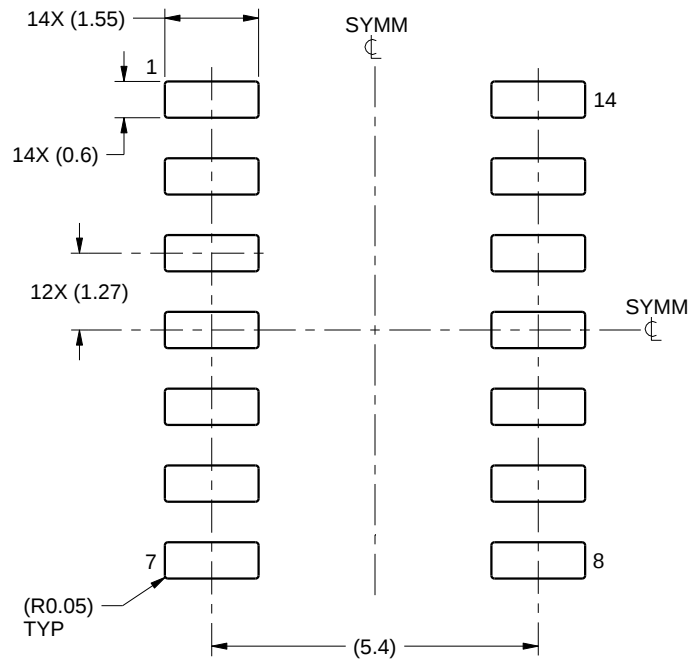
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

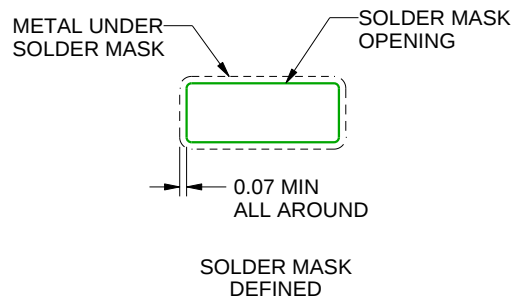
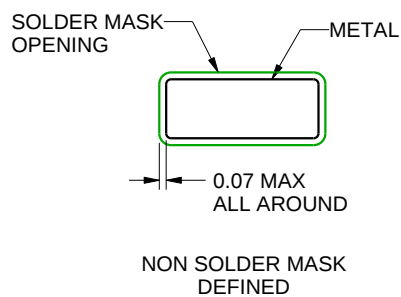
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

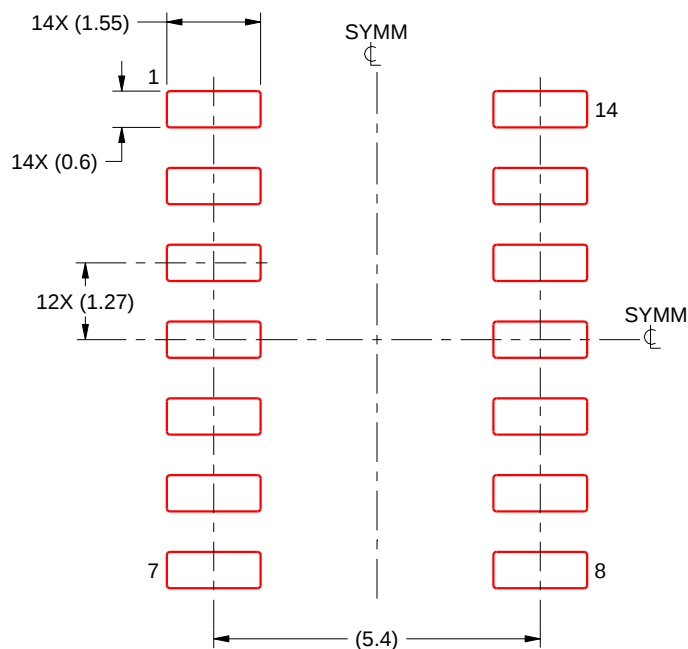
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

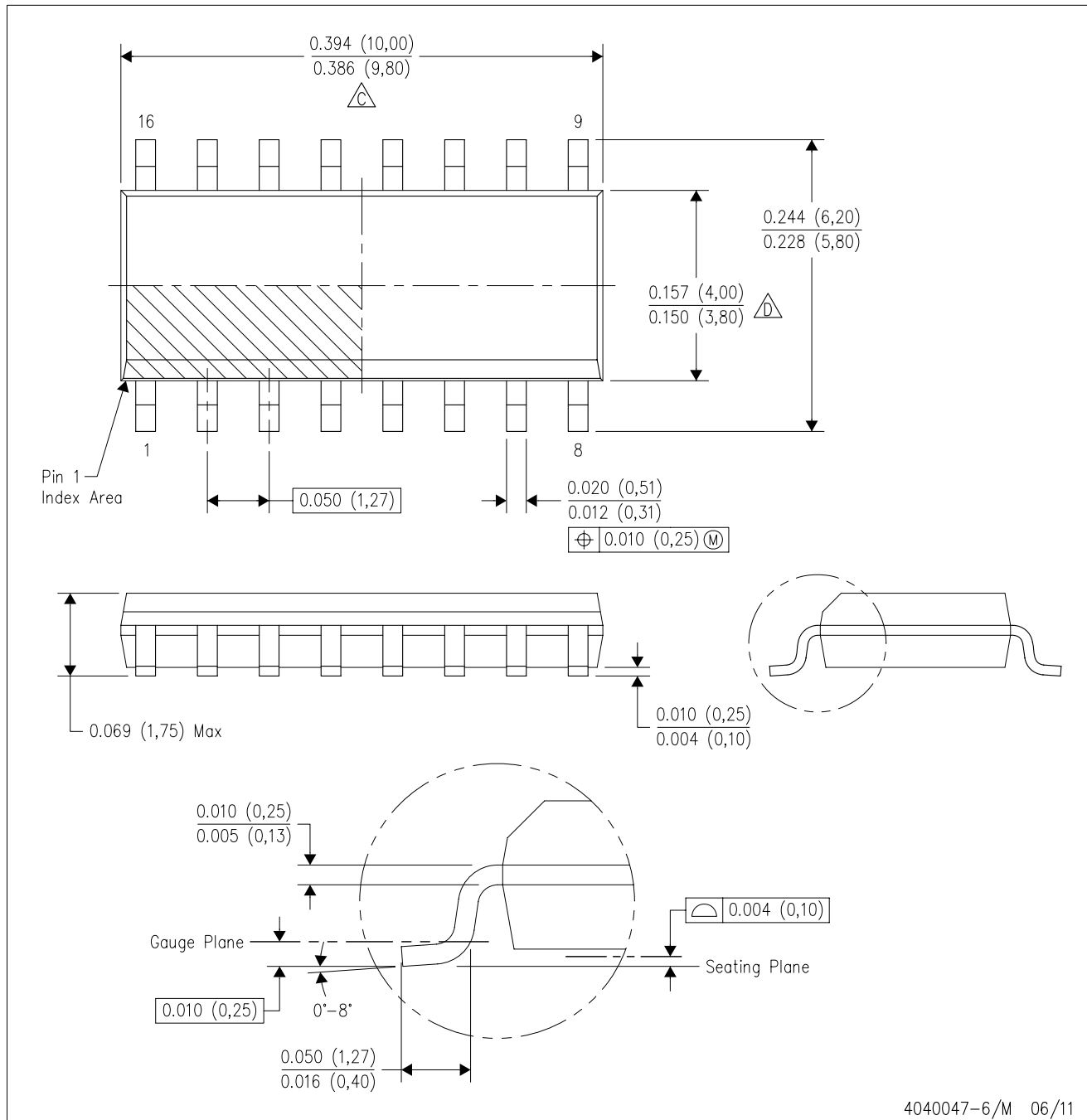
4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AC.

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